

GENERAL DESCRIPTION

This document describes the specification for the IDTF1320 **D**igital **P**re-**D**istortion Demodulator for PA linearization. This device is one of 2 variants to cover common UTRA bands. See the Part# Matrix below for details.

COMPETITIVE ADVANTAGE

In typical basestation transmitters a digital pre-distortion loop is employed to improve the Transmitter performance. The signal coming out of the PA is sampled so that the I&Q data at Baseband can be pre-distorted before being sent to the Tx DAC to counteract the distortion inherent in the downstream PA. The signal coupled from the PA is adjusted via a digital step attenuator to a lower level and then sub-sampled at an IF frequency of ~200 MHz which necessitates the need for a highly linear demodulator to downmix to quadrature IF from the Transmit frequency. By sampling IF_I and IF_Q independently and then digitally combining these signals, an effective doubling of the sample rate can be achieved. Any distortion in this path will degrade the performance of the DPD algorithm. By utilizing an ultra-linear demodulator w/integrated DSA such as the IDTF1320, the ACLR and/or power consumption of the full Tx system can be improved significantly.

- ✓ DPD full path ACLR: ↓ **1 dB**
- ✓ I_{cc}: DPD function Power Consumption ↓ **40%**
- ✓ **Zero-Distortion™ Demod** eliminates **2 IF amps**
- ✓ **Integrates 2 BPFs, 2 Baluns, 2 SP2Ts**
- ✓ Glitch-Free™ gain control



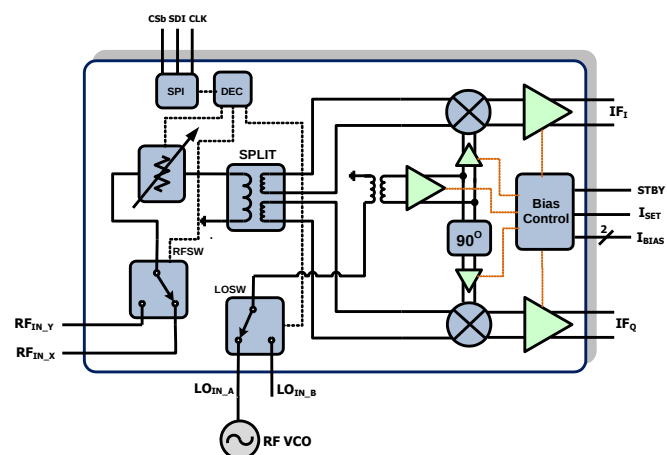
PART# MATRIX

Part#	RF range	UTRA bands	IF freq range	Typ. Gain	Injection
F1320	550 - 1150	5,6,8,12,13,14,17	20 - 350	12.5	High Side or Low Side
F1370	1300 - 2900	1,2,3,4,9,10,7,21, 24, 38	20 - 500	12.5	High Side or Low Side

FEATURES (I OR Q PATH)

- Wide flat performance IF BW
- Wide RF and LO BWs (~ 0.8 GHz)
- Ideal for Multi-Carrier Systems
- **Drives ADC directly**
- Ultra linear **+43 dBm IP_{3o}**
- Low Noise Figure
- Excellent ACLR performance
- **200 Ω** output impedance
- Fully integrated DPD demodulator
- **6x6 36 pin package**
- Standby Mode w/Fast Recovery
- I_{cc}: **262 mA**

DEVICE BLOCK DIAGRAM



ORDERING INFORMATION

Omit IDT prefix
IDTF1320NBGI8
 RF product Line
 0.8 mm height package
 Tape & Reel
 Green
 Industrial Temp range



ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND	-0.3V to +5.5V
SW_Latch, DATA, CSb, CLK	0V to 3.6V
STBY	0V to V _{CC}
IF_I+, IF_I-, IF_Q+, IF_Q-	1V to (V _{CC} + 0.3V)
IF_BiasI, IF_BiasQ to GND	-0.3V to +1.2V
LO_ADJ to GND	2.1V to 4.0V
RF Input Power (Into RFIN_X or RFIN_Y)	+27 dBm
Continuous Power Dissipation	2.5W
θ _{JA} (Junction – Ambient)	+40°C/W
θ _{JC} (Junction – Case) The Case is defined as the exposed paddle	+3°C/W
Operating Temperature Range (Case Temperature)	T _C = -40°C to +105°C
Maximum Junction Temperature	150°C
Storage Temperature Range	-65°C to +150°C
Moisture Sensitivity Level	1
Lead Temperature (soldering, 10s)	+260°C

Stresses above those listed above may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

IDTF1320 SPECIFICATION

Refer to Typical Application Circuit when operated with $V_{CC} = +5.0V$, $T_{CASE} = 25^{\circ}C$, $F_{RF} = 860\text{ MHz}$, $F_{LO} = 1060\text{ MHz}$, Gain = G_{MAX} , $P_{LO} = 0\text{ dBm}$, $T_C = +25^{\circ}C$, STBY = GND, unless otherwise noted. Full Lineup measured through to I or Q path. IF Transformers and RF trace losses de-embedded.

Parameter	Comment	Symbol	min	typ	max	units
Logic Input High	For STBY, DATA, CSb, CLK, SW_Latch	V_{IH}	2.3			V
Logic Input Low	For STBY, DATA, CSb, CLK, SW_Latch	V_{IL}			0.5	V
Logic Current	$V_H = 2.3V$, $V_L = 0V$	I_{IH} , I_{IL}	-135		+10	μA
Supply Voltage(s)	All V_{CC} (operating range)	V_{CC}		4.75 to 5.25		V
Temperature Range	Operating Range	T_{CASE}	-40		+105	degC
Supply Current	Total V_{CC}	I_{SUPP}		262	290¹	mA
Supply Current	Standby Mode: STBY > V_{IH}	I_{STBY}		22	27	mA
RF Freq Range	Sets LO freq range	F_{RF}	700		1100	MHz
IF center Freq Range	Sets LO freq range	F_{IF}	100		250	MHz
Oversample Operating Range	- Measure Gain at I&Q - Gain setting = G_{MAX} $F_{LO} = 950\text{ MHz}$, 1080 MHz - Gain Delta < 2.5 dB	F_{RFD}	550		1150	MHz
Oversample IF Range	- Measure Gain at I&Q - Gain setting = G_{MAX} $F_{LO} = 950\text{ MHz}$, 1080 MHz - Gain Delta < 2.5 dB	F_{IFD}	20		350	MHz
IF Linearity BW	- RF Freq = 860 MHz - IP3O > +39 dBm - From RF_INX to I+, I- & Q+, Q- - Pin = -11 dBm/Tone - Gain setting = G_{MAX}	IF_{LIN}	100		300	MHz
RF Linearity BW	- IF Freq = 200 MHz - IP3O > +37.5 dBm - From RF_INX to I+, I- & Q+, Q- - Pin = -11 dBm/Tone - Gain setting = G_{MAX}	RF_{LIN}	700		1100	MHz
LO Freq Range	Operating Range	F_{LOH}	500		1300	MHz
LO Power	Operating Range	P_{LO}		-3 to +3		dBm
RF Input Impedance	Single Ended (RL > 10 dB)	Z_{RF}		50		Ω
IF Output Impedance	Differential (RL > 10 dB)	Z_{IF}		200		Ω
LO port Impedance	Single Ended (RL > 10 dB)	Z_{LO}		50		Ω
Gain maximum	- From RF_INX to I+, I- & Q+, Q- - Gain setting = G_{MAX} - Pin = -11 dBm	G_{MAX} or $ATTN_{MIN}$	11	12.5	14	dB
Gain minimum	- From RF_INX to I+, I- - Gain setting = G_{MIN} - Pin = +14 dBm	G_{MIN} or $ATTN_{MAX}$	-15	-13.5	-12	dB



IDTF1320NBGI Datasheet

DPD Demodulator for PA Linearization

550MHz to 1150MHz

IDTF1320 SPECIFICATION - CONTINUED

Refer to Typical Application Circuit when operated with $V_{CC} = +5.0V$, $T_{CASE} = 25C$, $F_{RF} = 860\text{ MHz}$, $F_{LO} = 1060\text{ MHz}$, Gain = G_{MAX} , $P_{LO} = 0\text{ dBm}$, $T_C = +25^\circ C$, STBY = GND, unless otherwise noted. Full Lineup measured through to I or Q path. IF Transformers and RF trace losses de-embedded.

Parameter	Comment	Symbol	min	typ	max	units
Noise Figure	- From RF_INX to I+,I- out - Gain setting = G_{MAX}	NF		18.3		dB
Output IP3 – G_{MAX}	- Measured at I+,I- and Q+,Q- $P_{IN} = -11\text{ dBm}$ per tone 5 MHz Tone Separation - Gain setting = G_{MAX}	$IP3_{MAX}$	39	43		dBm
Output IP3 – G_{-20}	- Measured at I+,I- and Q+,Q- $P_{IN} = +9\text{ dBm}$ per tone 5 MHz Tone Separation - Gain setting = G_{-20}	$IP3_{-20}$	39^2	42		dBm
2 nd Harmonic	- Measured at I+,I- and Q+,Q- $P_{IN} = -11\text{ dBm}$ $F_{RF} = 860$, $F_{LO} = 970$ - Gain setting = G_{MAX}	H2	-70	-76		dBc
Output IP2	- Measured at I+,I- and Q+,Q- $P_{IN} = -11\text{ dBm}$ per tone 5 MHz Tone Separation - Gain setting = G_{MAX}	$IP2_O$	59	65		dBm
Output compression	- Measured at I+,I- and Q+,Q- $P_{IN} = +4\text{ dBm}$ - Gain setting = G_{MAX}	C		0.3	1	dB
Gain Ripple1	- Fixed LO = 1020 MHz - RF = 650 to 1000 MHz - IF = 20 to 370 MHz	Ripple1		0.8	1.4	dB
Gain Ripple2	- Fixed LO = 1061.5 MHz - RF = 591.5MHz to 1041.5MHz - IF = 20 to 470 MHz	Ripple2		1.1	1.5	dB
Group Delay Distortion	- Fixed LO = 1020 MHz - RF = 650 to 1000 MHz - IF = 20 to 350 MHz	GDD		2		nsec
Quadrature Amplitude Balance	- From RF_INX to I+,I- & Q+,Q- - Gain setting = G_{MAX} $P_{in} = -11\text{ dBm}$	BAL_G	-0.2		0.2	dB
Quadrature Phase Balance	$F_{RF} = 860$, $F_{LO} = 1060$ - Measure with 20 GSa/sec scope	BAL_ϕ	-3		+3	degrees
Amplitude Balance over environmentals	$F_{RF} = 860$, $F_{LO} = 1060$ $T_C = -40C$ to $100C$ - LO drive = -3 dBm to +3 dBm - Measure with 20 GSa/sec scope	BAL_{GA}	-0.4		+0.4	dB
Quadrature Phase Balance over environmentals	$F_{RF} = 860$, $F_{LO} = 1060$ $T_C = -40C$ to $100C$ - LO drive = -3 dBm to +3 dBm - Measure with 20 GSa/sec scope	$BAL_{\phi A}$	-3		+3	degrees
LO to IF leakage		ISO_{LI}		-30	-25	dBm
LO to RF leakage		ISO_{LR}		-40		dBm
RF to IF isolation		ISO_{RI}		-32	-23	dB
Attenuator Range		Range		25.5		dB

IDTF1320 SPECIFICATION - CONTINUED

Refer to Typical Application Circuit when operated with $V_{CC} = +5.0V$, $T_{CASE} = 25^{\circ}C$, $F_{RF} = 860\text{ MHz}$, $F_{LO} = 1060\text{ MHz}$, Gain = G_{MAX} , $P_{LO} = 0\text{ dBm}$, $T_C = +25^{\circ}C$, STBY = GND, unless otherwise noted. Full Lineup measured through to I or Q path. IF Transformers and RF trace losses de-embedded.

Parameter	Comment	Symbol	min	typ	max	units
Attenuator Glitching	- Step from 15.5 to 16 dB - Step from 16 to 15.5 dB - Measure maximum excursion	$ATTN_G$		0.5		dB
Attenuator Step Accuracy		DNL		0.2		dB
Attenuator Abs. Accuracy		INL		0.2	0.5	dB
Attenuator Resolution		LSB		0.5		dB
Serial Clock Speed	SPI 3 wire bus	F_{CLOCK}		20	50	MHz
Data to Clock Setup	SPI 3 wire bus	T_S	3			ns
Data to Clock Hold	SPI 3 wire bus	T_H	3			ns
Clock to CS Setup	SPI 3 wire bus	T_{EN}	3			ns
Clock Pulse Width	SPI 3 wire bus	T_W	5			ns
LO Switch Isolation		ISO_{LOSW}		-45	-36	dB
RF Switch Isolation		ISO_{RFSW}		-45	-43	dB
RF Switch and attenuator settling times³						
EN bit on	- LO_INA: 1050MHz, +3dBm - RF_INX: 850MHz, -10dBm	EN_{ON}		100		nsec
EN bit off		EN_{OFF}		50		
RF switched X to Y (no Y signal)		RF_{SWXY}		130		
RF switched Y to X (no Y signal)		RF_{SWYX}		200		
LO switched A to B (no B signal)		LO_{SWAB}		40		
LO switched B to A (no B signal)		LO_{SWBA}		20		
Attenuator switched 0dB to 25.5dB (max)		ATT_{SETL}		300		
Attenuator switched 25.5dB (max) to 0dB				300		
Attenuator switched 15.5dB to 16dB				250		
Attenuator switched 16dB to 15.5dB				300		

SPECIFICATION NOTES:

- 1 – Items in min/max columns in **bold italics** are Guaranteed by Test
- 2 – All other Items in min/max columns are Guaranteed by Design Characterization
- 3 – Excludes SPI write time

POWER-ON SEQUENCE

The power-on sequence ensures F1320 works in default mode once powered on. If the F1320 is programmed after applying DC power, the following power-on sequence is not needed.

The power-on sequence should be:

1. CSb & SW_LATCH must be set low at power-on
2. Once powered on, first set SW_LATCH high, then set CSb high
3. Proceed with normal programming.

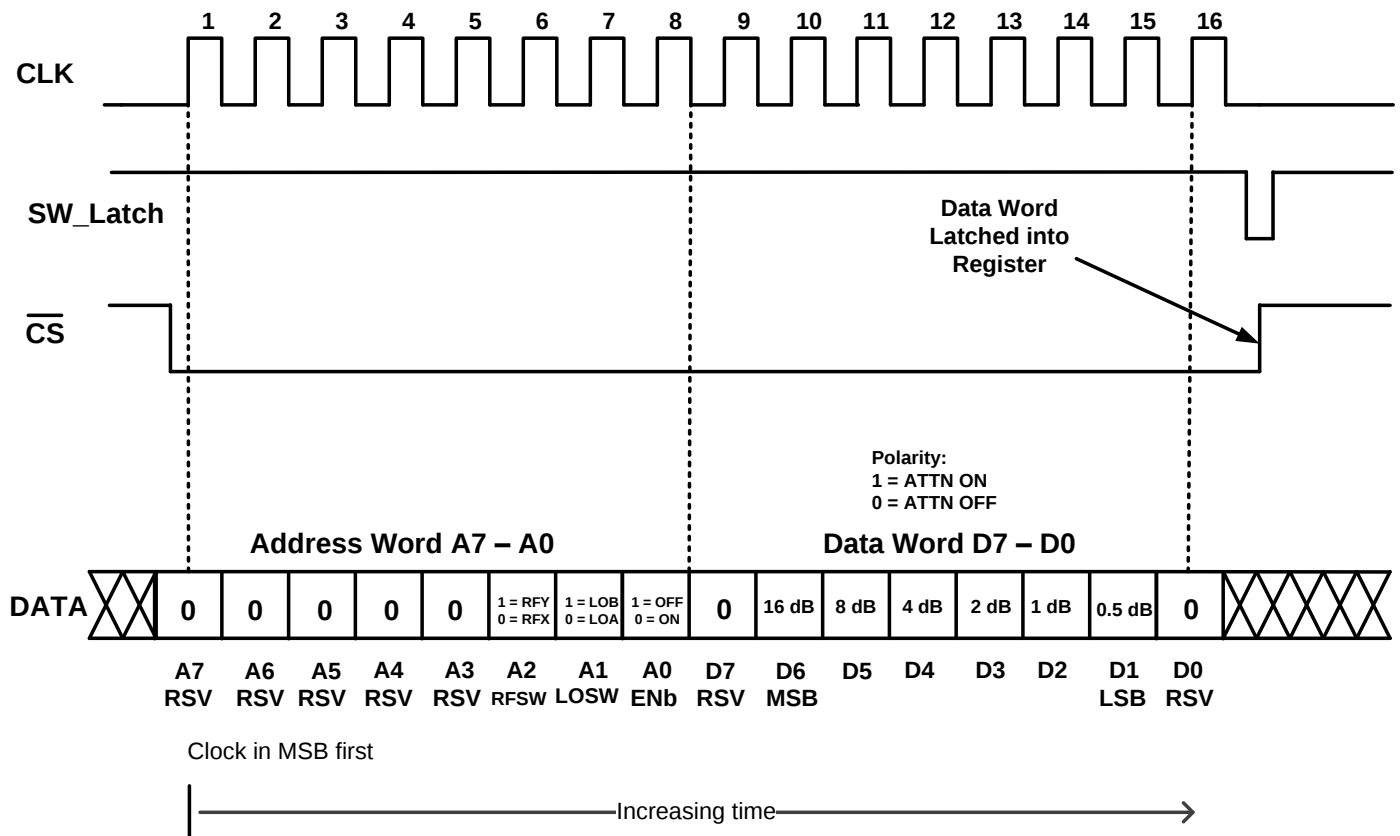
The default state after using power-on sequence:

- Maximum attenuation
- RF_INX, LO_INA selected
- Normal operation (not Standby Mode)

SERIAL PROGRAMMING

The device is programmed via the serial port by asserting Chip Select (CSb). Note: Most-Significant-Bit first, where the Address Word is the Most-Significant-Byte.

Serial mode timing diagram high level:

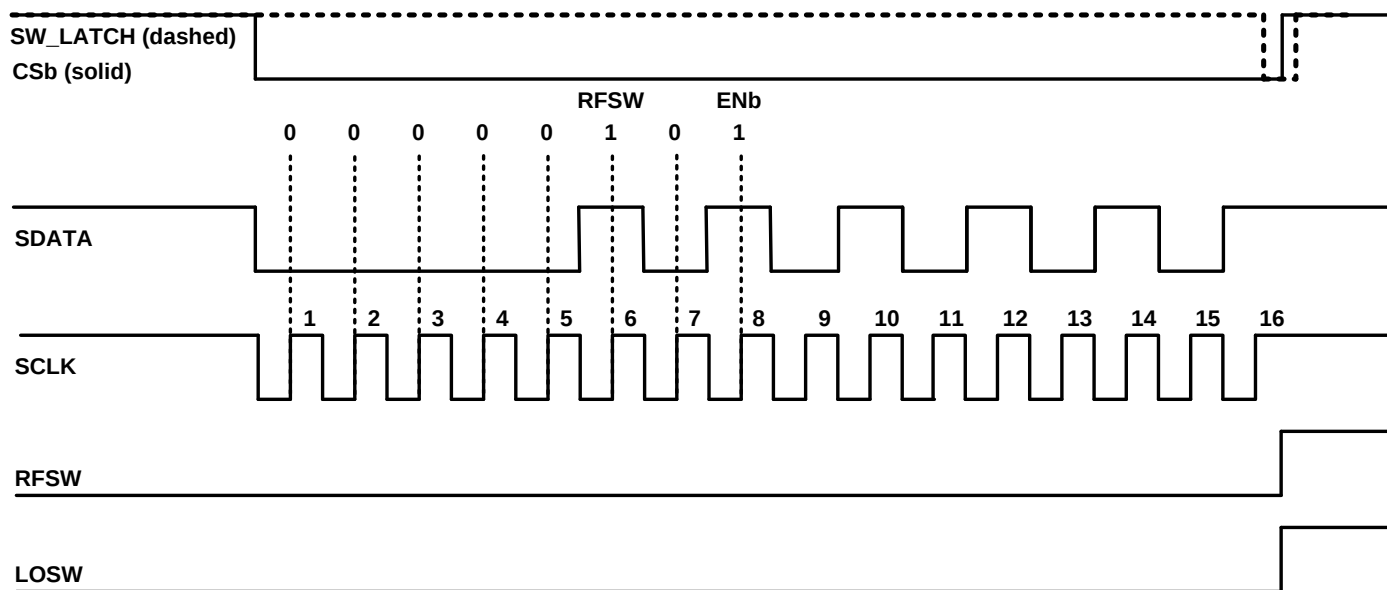


TO PROGRAM THE SERIAL INTERFACE:

If CSb is de-asserted (set to high), the serial interface will ignore the CLK line. Once CSb is asserted (set to low), the serial interface will recognize the CLK and any data present on DATA will be clocked into the registers with each rising CLK edge. After the 16th CLK cycle, and before the 17th CLK cycle, CSb must be de-asserted to successfully program the part with the desired bytes. If CSb is de-asserted before the 16th CLK cycle, or after the 17th CLK cycle, there is no guarantee that the correct bytes will be programmed and the user will have to re-program the interface in accordance with the aforementioned procedure.

SW_LATCH PROGRAMMING SEQUENCE

- When SW_LATCH is pinned high during the programming sequence, "RFSW" and "ENb" registers cannot be programmed and therefore will not toggle.
- If SW_LATCH is pinned low during the programming sequence, the "RFSW" and "ENb" register will toggle. This can be prevented with the "Programming Sequence" below.

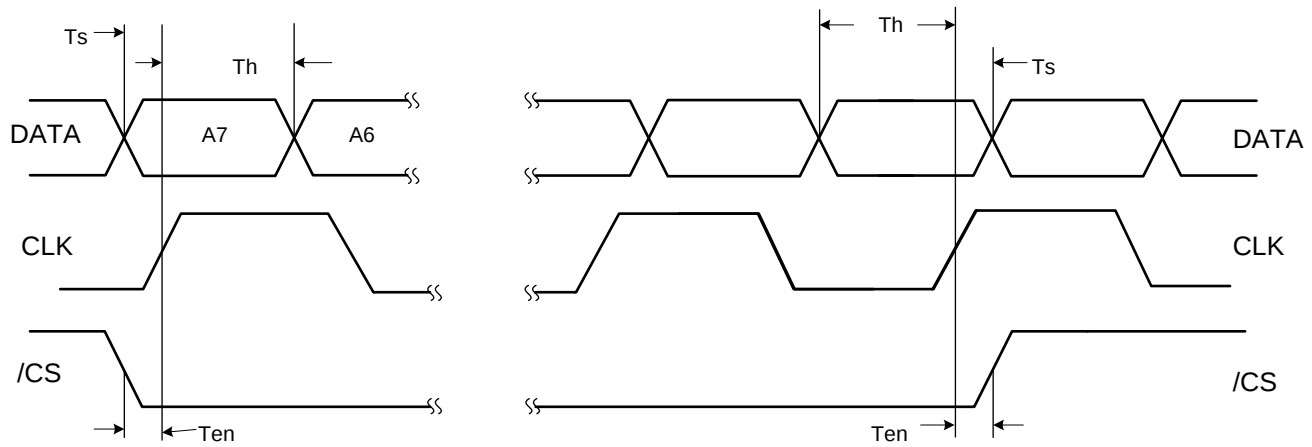


SEQUENCE FOR PROGRAMMING REGISTERS A<2>:A<0>

- 1) SW_Latch = 1; CSb = 0
- 2) CLK in 8- or 16-bit word, *do not de-assert (pull high) CSb*
- 3) Set SW_LATCH = 0 while CSb = 0 remains)
- 4) With SW_Latch = 0, set CSb = 1
- 5) Set SW_Latch = 1
- 6) Program complete

SPECIAL NOTE REGARDING PHASE OF I & Q:

- When LO is high-side injected, IF_I leads IF_Q by 90 degrees
- When LO is low-side injected, IF_Q leads IF_I by 90 degrees

SERIAL MODE TIMING DIAGRAM ZOOM:


- Data is shifted with the rising edge of CLK when /CS is low
- The rising edge of /CS latches data into the device

LOGIC TRUTH TABLE:

STBY	SW_LATCH	MODE	WRITE ACCESS
0	0	Operating Mode	A2:A0 Enabled, D7:D0 Enabled
0	1	Operating Mode	A2:A0 Disabled, D7:D0 Enabled
1	0	Off	A2:A0 Enabled, D7:D0 Enabled
1	1	Off	A2:A0 Disabled, D7:D0 Enabled

F1320 ATTENUATION TABLE

The F1320 gain/attenuation setting is controlled by 6 bits in the data word. The device provides an added attenuation range from 0 dB to 25.5 dB in 0.5 dB steps. A “high” or “1” bit corresponds to attenuation stepped IN, while a “low” or “0” bit corresponds to attenuation stepped OUT.

F1320 DPD Demodulator - Attenuation Table (Data Word D7-D0)

BINARY	HEX	Added Atten (dB)		BINARY	HEX	Added Atten (dB)
00000000	00	0		00110100	34	13
00000010	02	0.5		00110110	36	13.5
00000100	04	1		00111000	38	14
00000110	06	1.5		00111010	3A	14.5
00001000	08	2		00111100	3C	15
00001010	0A	2.5		00111110	3E	15.5
00001100	0C	3		01000000	40	16
00001110	0E	3.5		01000010	42	16.5
00010000	10	4		01000100	44	17
00010010	12	4.5		01000110	46	17.5
00010100	14	5		01001000	48	18
00010110	16	5.5		01001010	4A	18.5
00011000	18	6		01001100	4C	19
00011010	1A	6.5		01001110	4E	19.5
00011100	1C	7		01010000	50	20
00011110	1E	7.5		01010010	52	20.5
00100000	20	8		01010100	54	21
00100010	22	8.5		01010110	56	21.5
00100100	24	9		01011000	58	22
00100110	26	9.5		01011010	5A	22.5
00101000	28	10		01011100	5C	23
00101010	2A	10.5		01011110	5E	23.5
00101100	2C	11		01100000	60	24
00101110	2E	11.5		01100010	62	24.5
00110000	30	12		01100100	64	25
00110010	32	12.5		01100110	66	25.5

Because the first and last bits of the Data Word are not presently used by the F1320, two additional hex character pairs exists for each of those in this table. For example, data words of either H00, H80, or H01 (binary “00000000,” “10000000,” or 00000001) will place the F1320 in its minimum attenuation state. Likewise, data words of either H66, HE6, or H67 (binary “01100110” or “11100110” or “01100111”) will place the F1320 in its maximum attenuation state of 25.5 added attenuation.

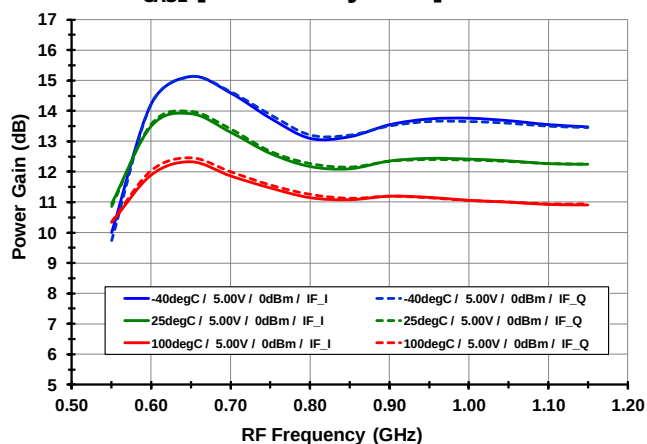
TYPICAL OPERATING CONDITIONS

Unless otherwise noted, for the TOC graphs, the following conditions apply

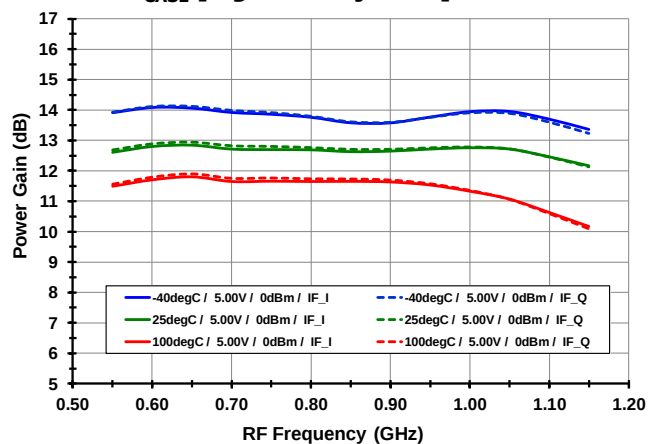
- **IF = 200 MHz**
- **Tone spacing = 5 MHz**
- **P_{out} ~ 1 dBm**
- **P_{in} = -11 dBm**
- **RF_X, LO_A, IF_I selected**
- **Attenuation Setting = 0 dB (min ATTN or G_{MAX})**
- **T_{CASE} = 25C**
- **V_{CC} = 5.00 V**
- **LO level = 0 dBm**
- **Output Transformer losses are de-embedded**
- **Input RF trace losses are de-embedded**

TOCs [Fixed IF] (-1-)

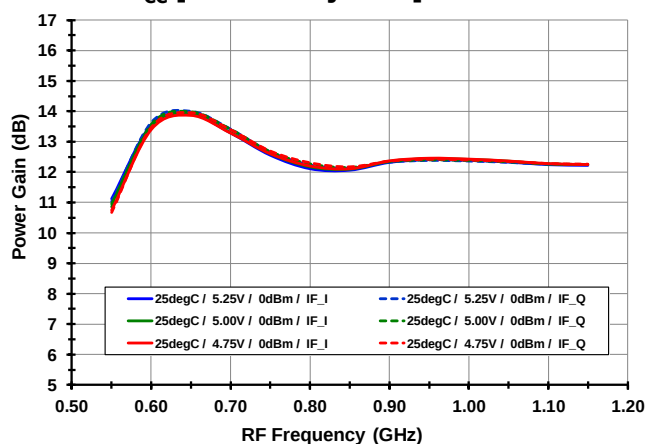
GAIN vs. T_{CASE} [Low Side Injection]



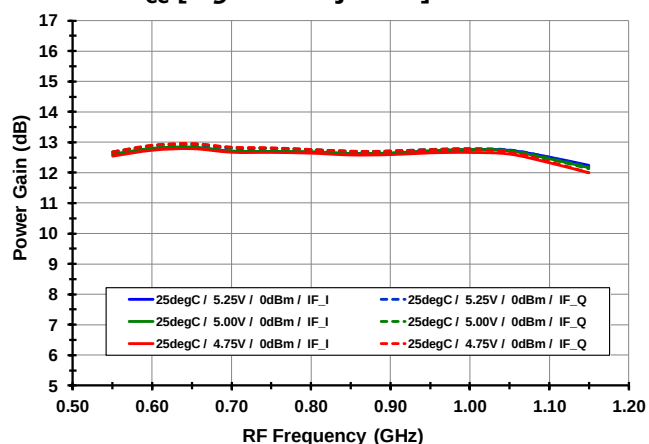
GAIN vs. T_{CASE} [High Side Injection]



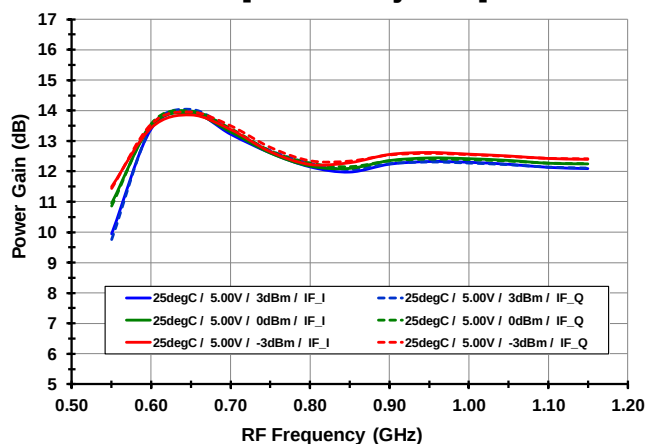
GAIN vs. V_{CC} [Low Side Injection]



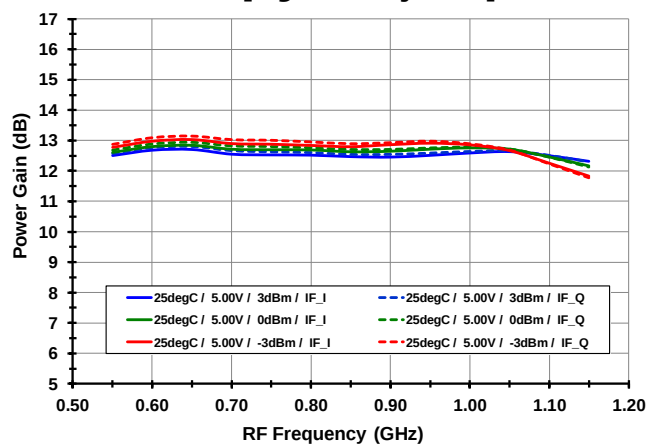
GAIN vs. V_{CC} [High Side Injection]



GAIN vs. LO level [Low Side Injection]

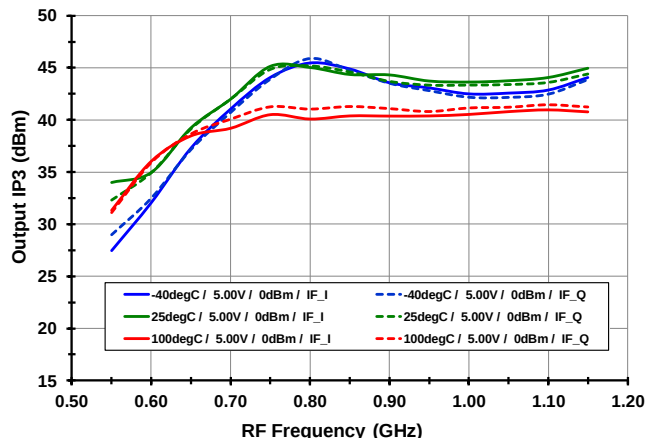


GAIN vs. LO level [High Side Injection]

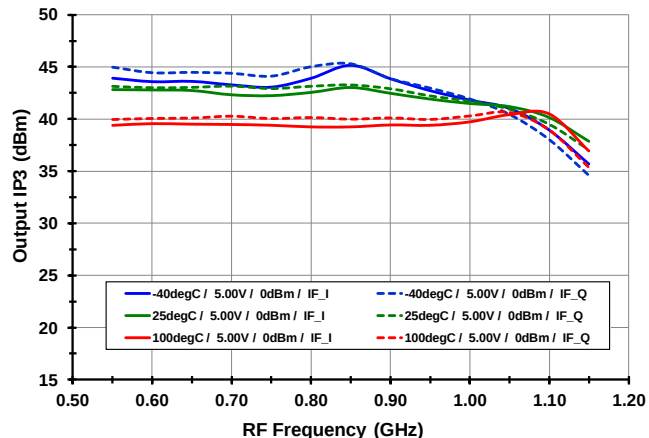


TOCs [Fixed IF] (-2-)

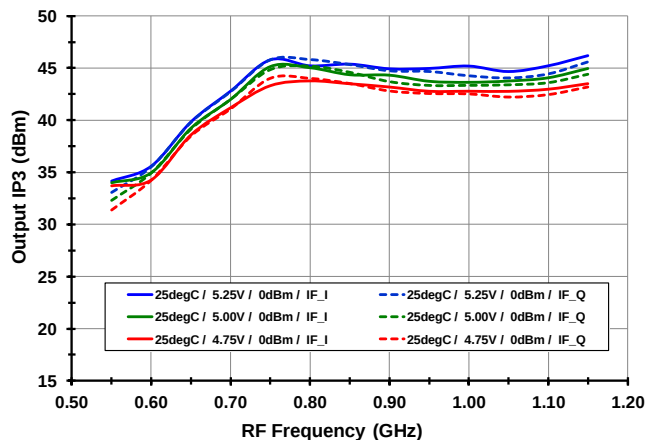
IP_{3O} vs. T_{CASE} [Low Side Injection]



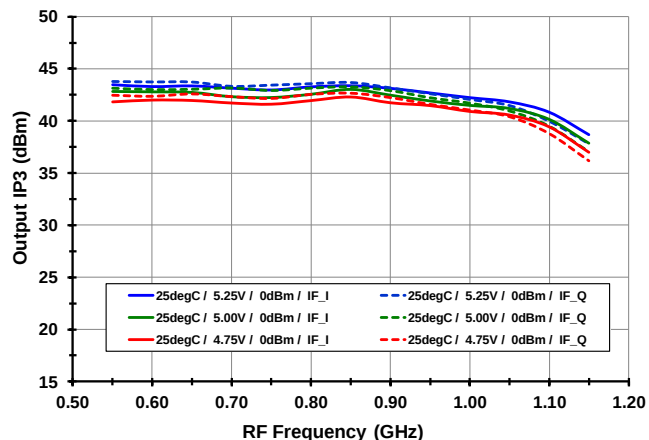
IP_{3O} vs. T_{CASE} [High Side Injection]



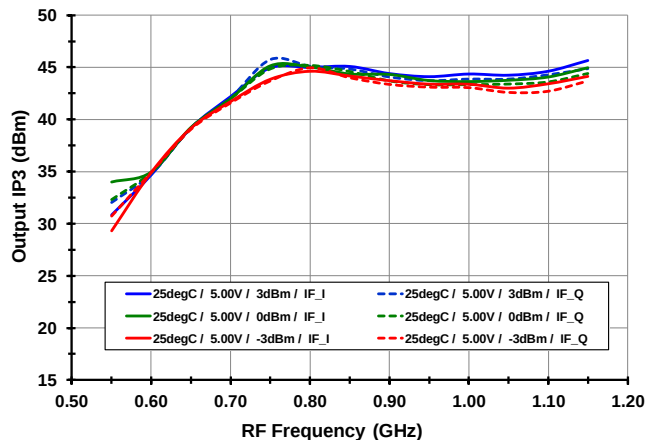
IP_{3O} vs. V_{CC} [Low Side Injection]



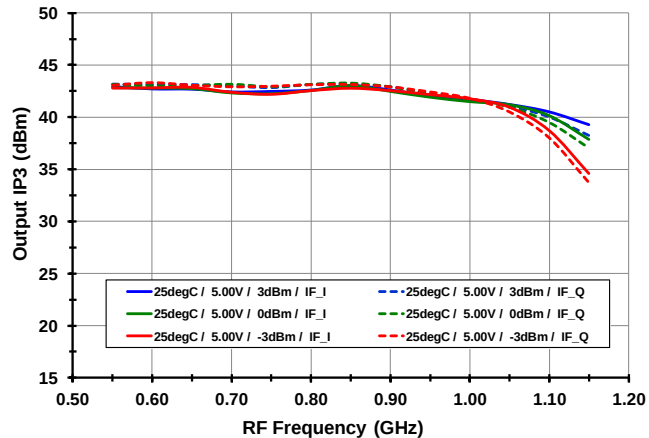
IP_{3O} vs. V_{CC} [High Side Injection]



IP_{3O} vs. LO level [Low Side Injection]

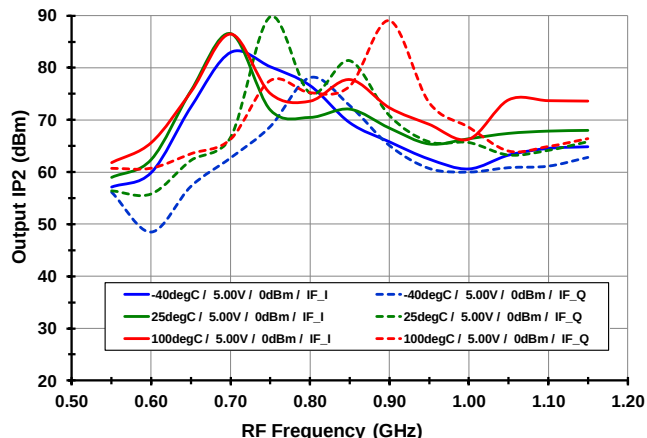


IP_{3O} vs. LO level [High Side Injection]

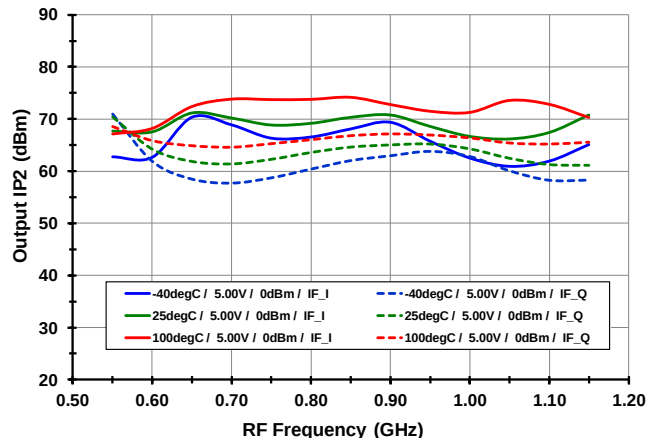


TOCs [Fixed IF] (-3-)

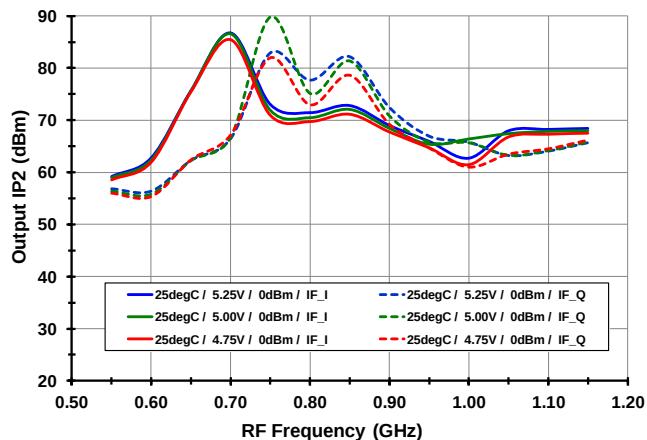
IP_{2O} vs. T_{CASE} [Low Side Injection]



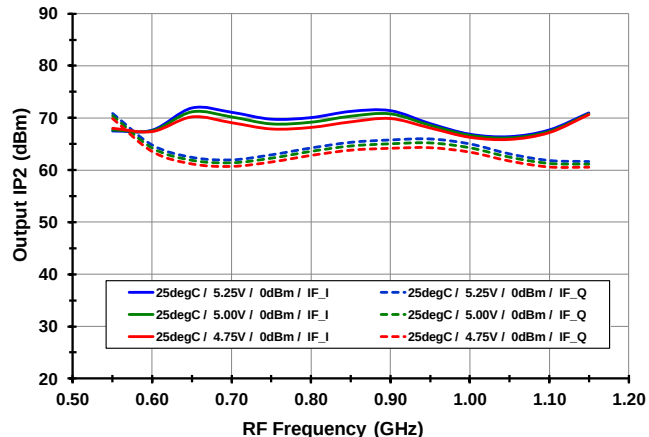
IP_{2O} vs. T_{CASE} [High Side Injection]



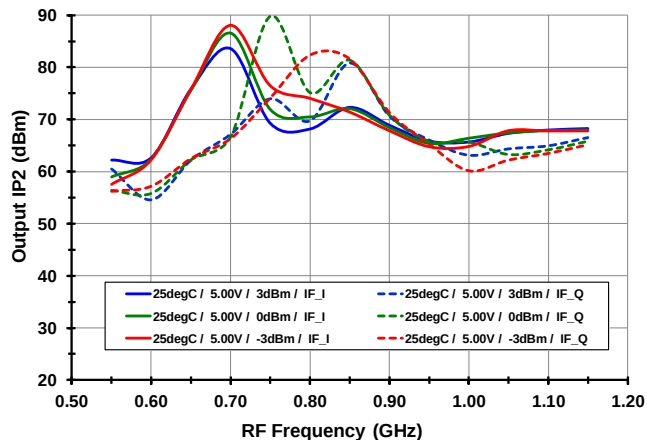
IP_{2O} vs. V_{CC} [Low Side Injection]



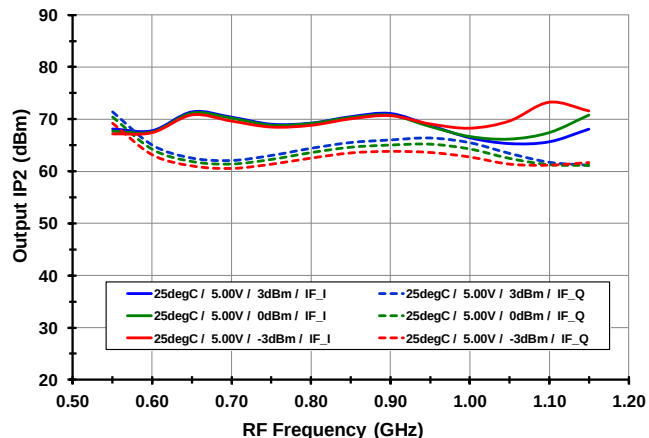
IP_{2O} vs. V_{CC} [High Side Injection]



IP_{2O} vs. LO level [Low Side Injection]

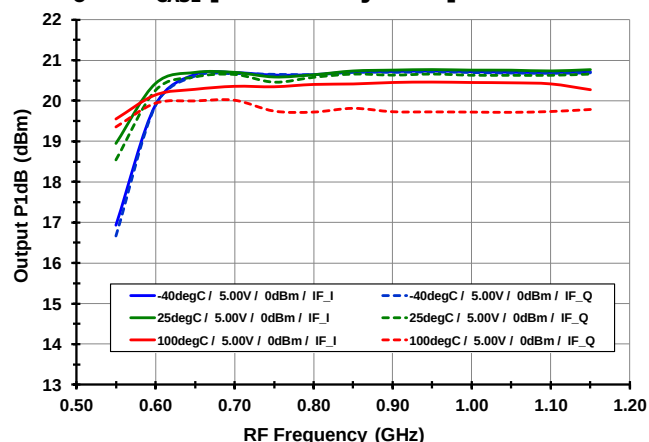


IP_{2O} vs. LO level [High Side Injection]

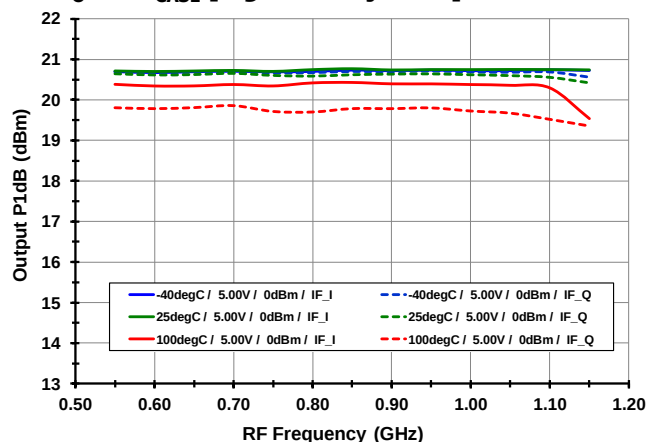


TOCs [Fixed IF] (-4-)

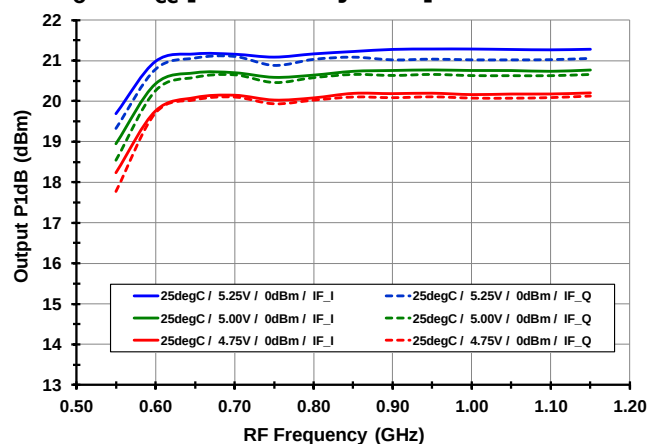
P1dB₀ vs. T_{CASE} [Low Side Injection]



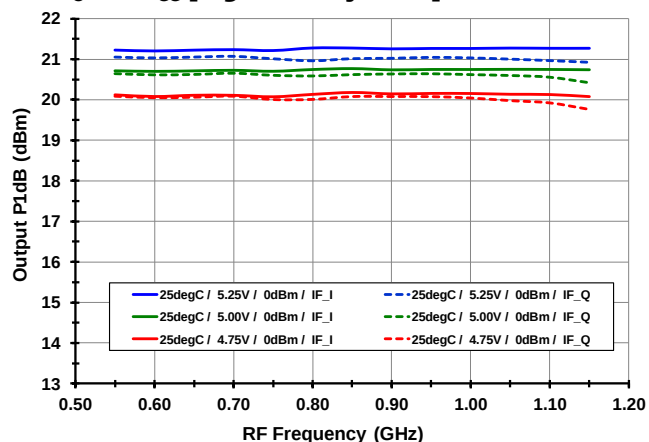
P1dB₀ vs. T_{CASE} [High Side Injection]



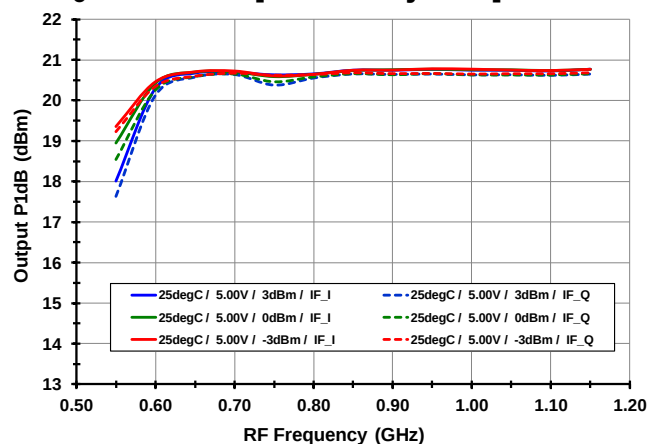
P1dB₀ vs. V_{CC} [Low Side Injection]



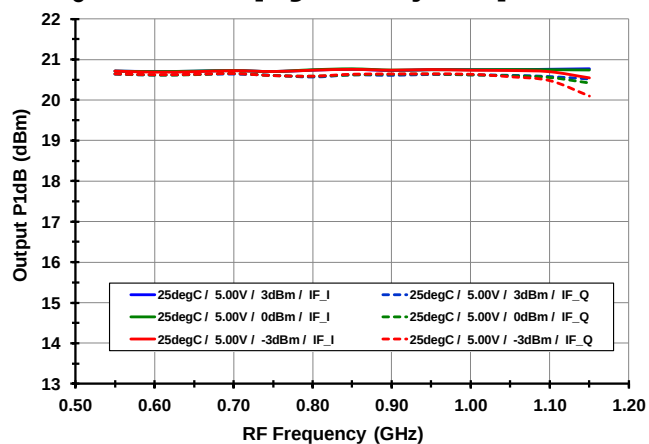
P1dB₀ vs. V_{CC} [High Side Injection]



P1dB₀ vs. LO level [Low Side Injection]

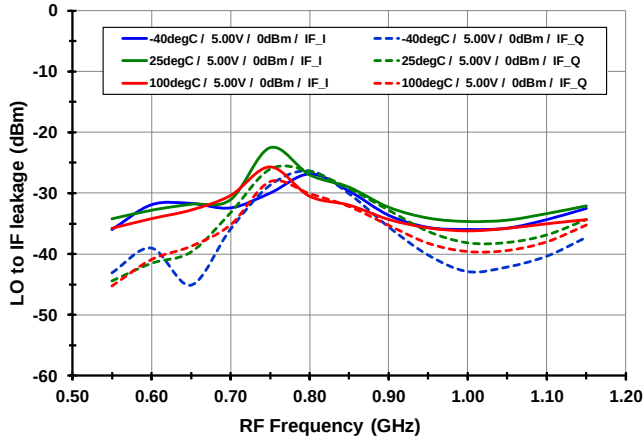


P1dB₀ vs. LO level [High Side Injection]

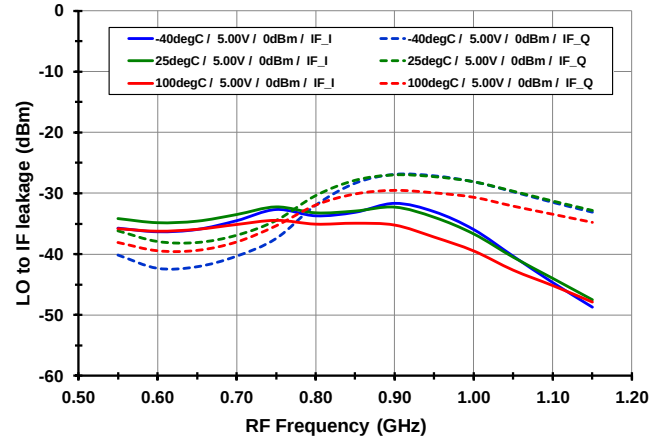


TOCs [Fixed IF] (-5-)

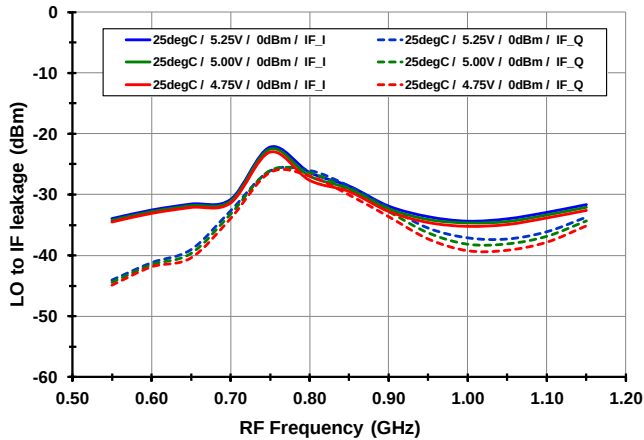
LO to IF vs. T_{CASE} [Low Side Injection]



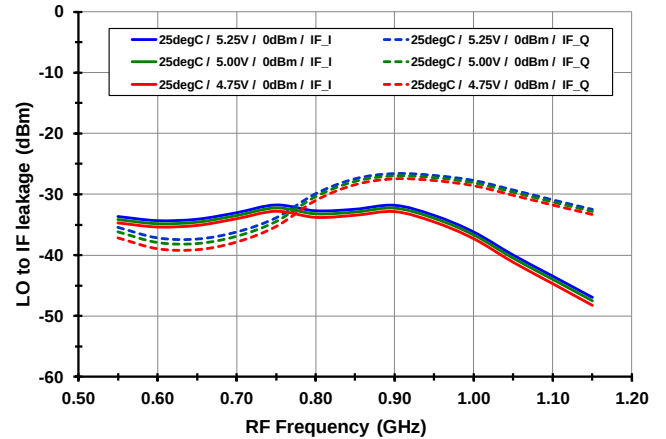
LO to IF vs. T_{CASE} [High Side Injection]



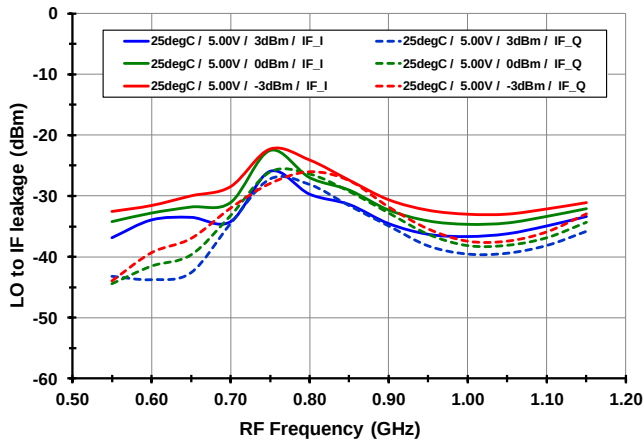
LO to IF vs. V_{CC} [Low Side Injection]



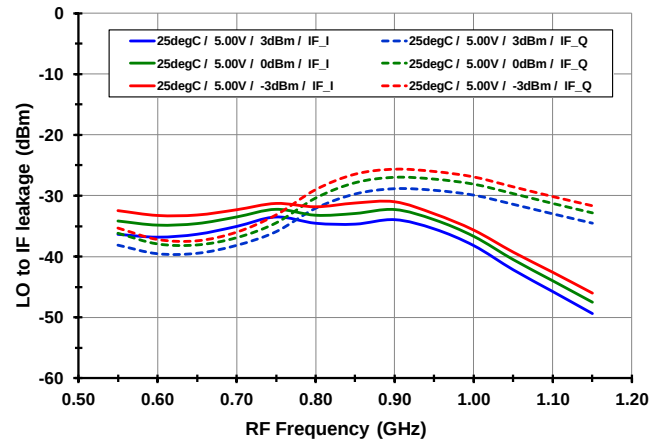
LO to IF vs. V_{CC} [High Side Injection]



LO to IF vs. LO level [Low Side Injection]

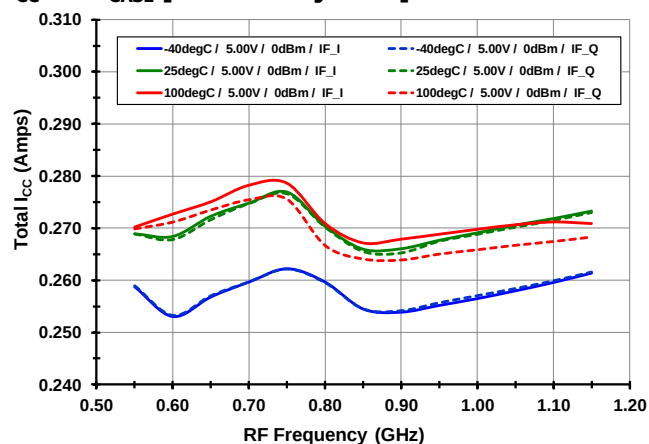


LO to IF vs. LO level [High Side Injection]

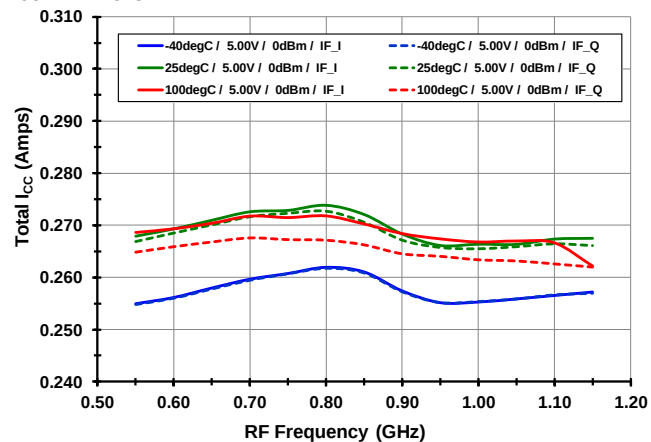


TOCs [Fixed IF] (-6-)

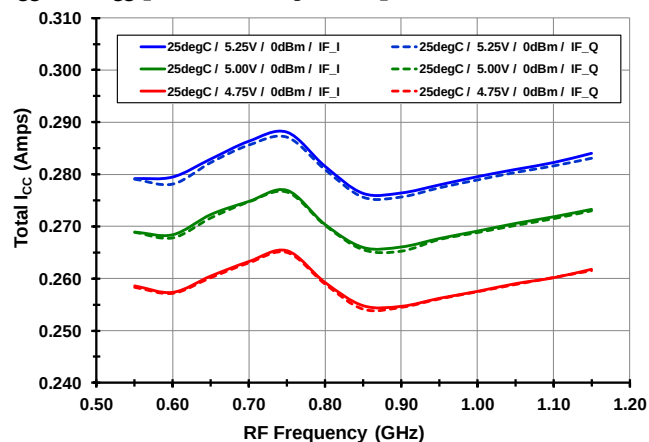
I_{CC} vs. T_{CASE} [Low Side Injection]



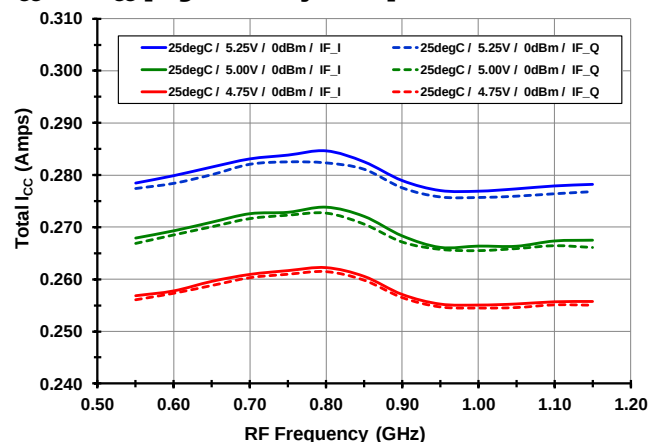
I_{CC} vs. T_{CASE} [High Side Injection]



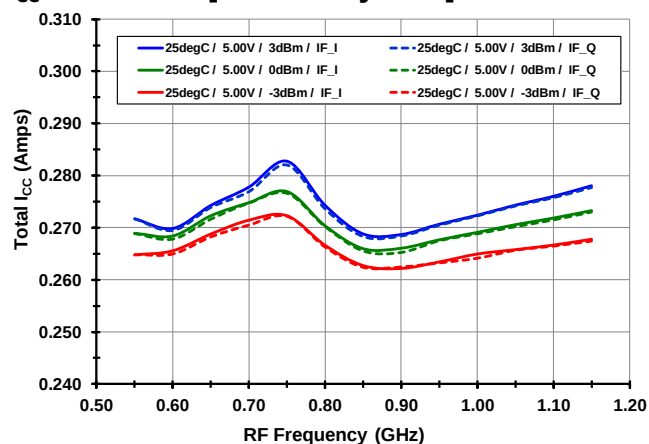
I_{CC} vs. V_{CC} [Low Side Injection]



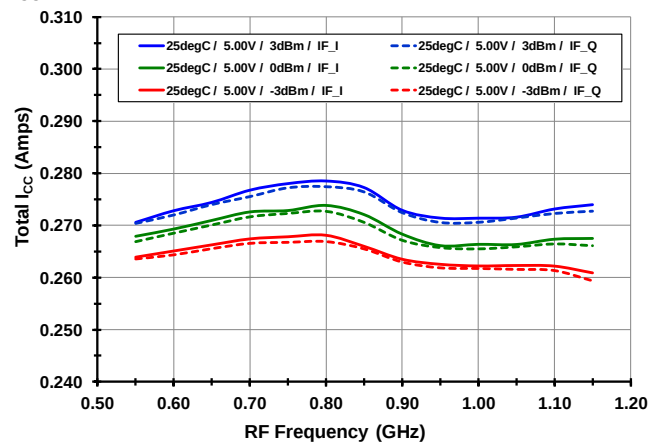
I_{CC} vs. V_{CC} [High Side Injection]



I_{CC} vs. LO level [Low Side Injection]

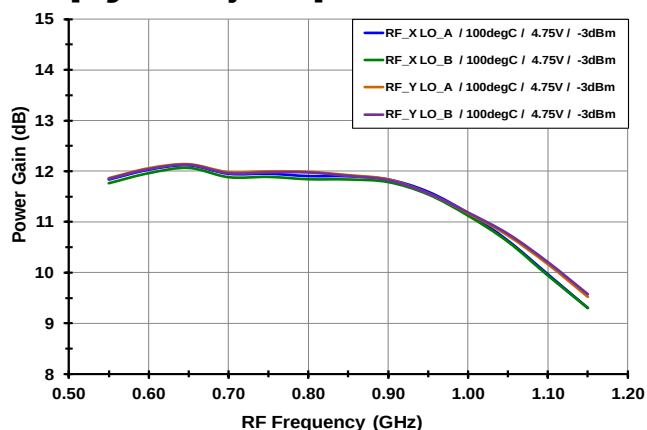


I_{CC} vs. LO level [High Side Injection]

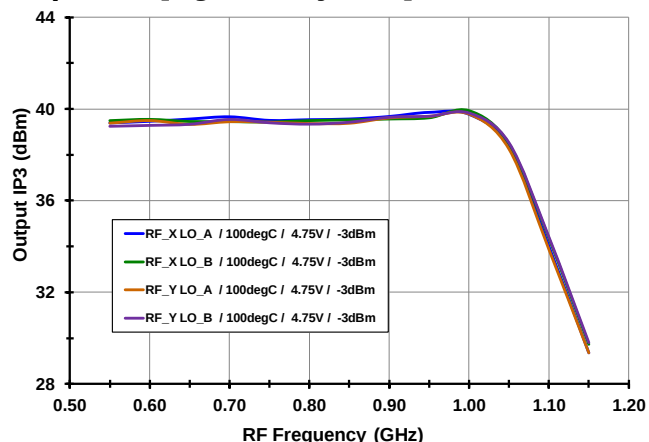


TOCs [vs. Switch Configuration, Extreme Conditions, IF_I only] (-7-)

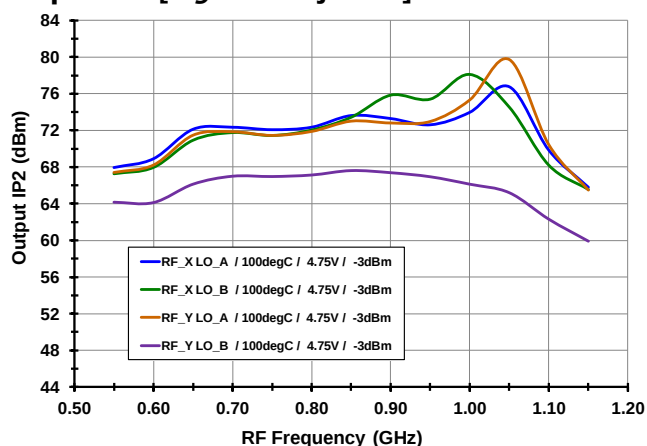
Gain [High Side Injection]



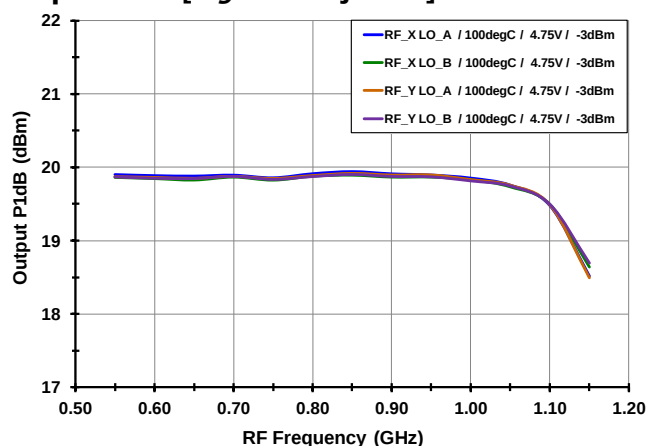
Output IP3 [High Side Injection]



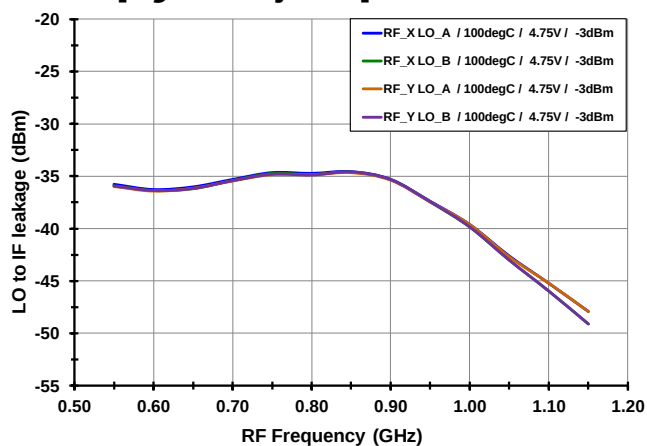
Output IP2 [High Side Injection]



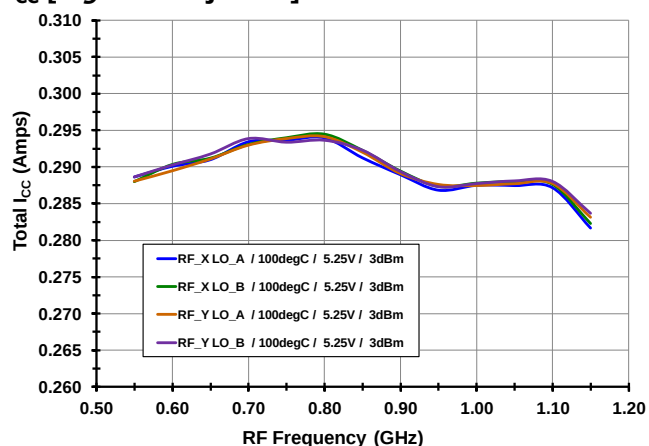
Output P1dB [High Side Injection]



LO to IF [High Side Injection]

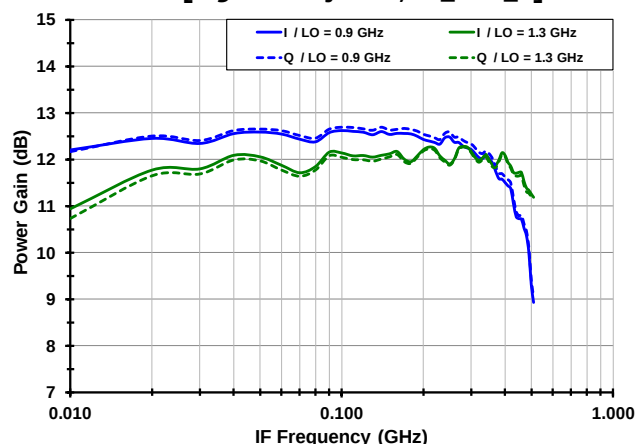


I_{CC} [High Side Injection]

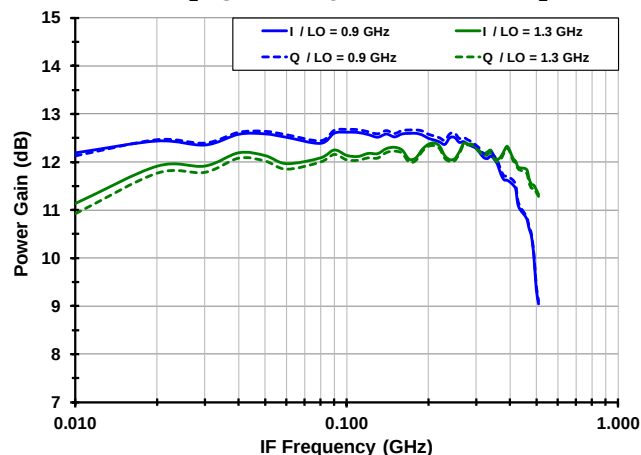


TOCs [Fixed LO] (-8-)

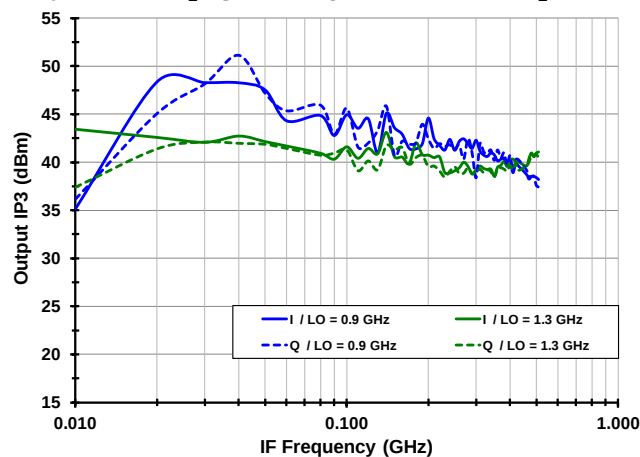
Gain Flatness [High Side Injection, RF_X LO_A]



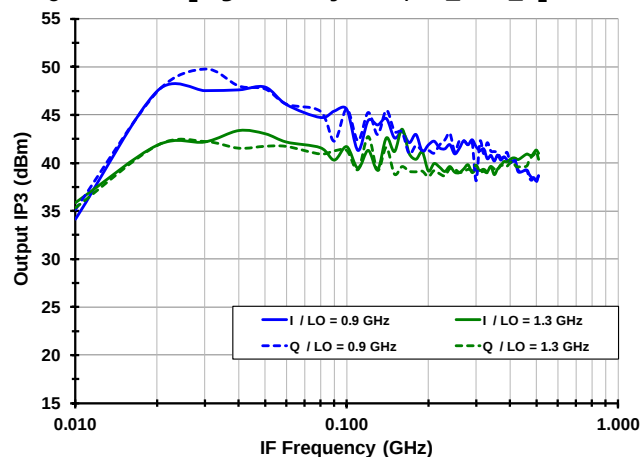
Gain Flatness [High Side Injection, RF_Y LO_B]



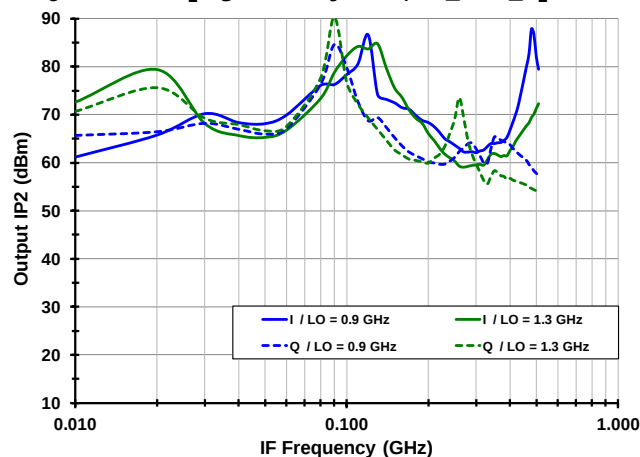
IP3₀ Flatness [High Side Injection, RF_X LO_A]



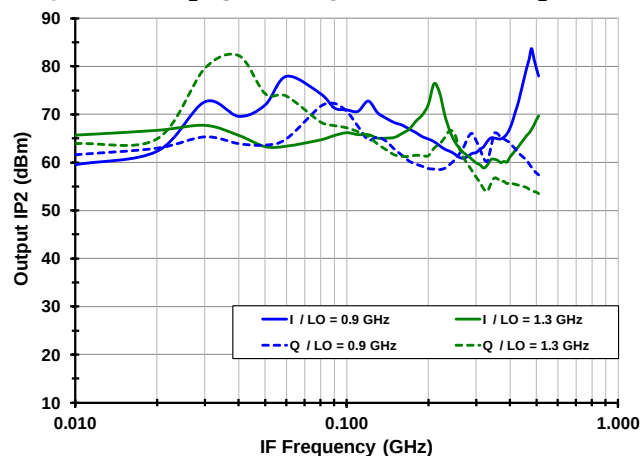
IP3₀ Flatness [High Side Injection, RF_Y LO_B]



IP2₀ Flatness [High Side Injection, RF_X LO_A]

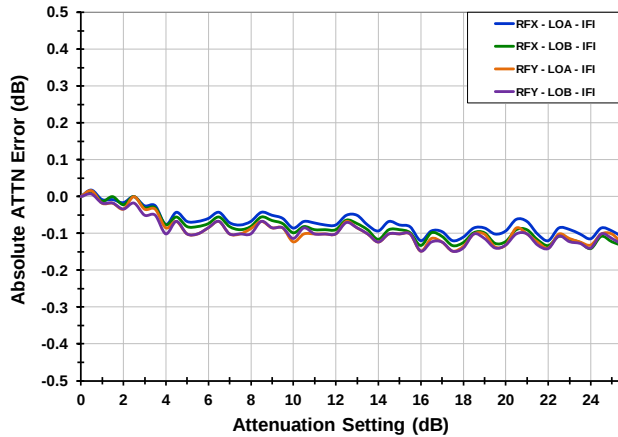


IP2₀ Flatness [High Side Injection, RF_Y LO_B]

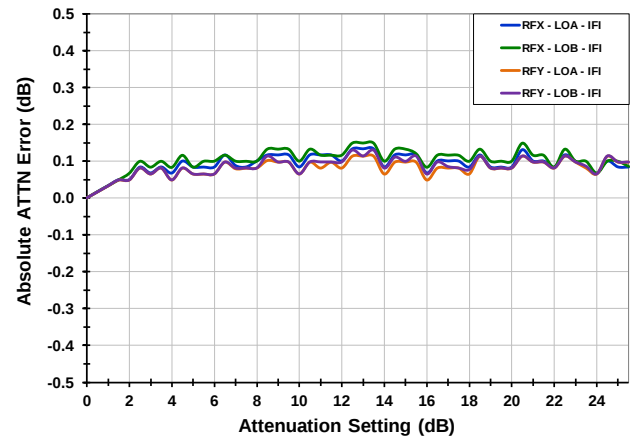


TOCs [vs. Attenuation Setting] (-9-)

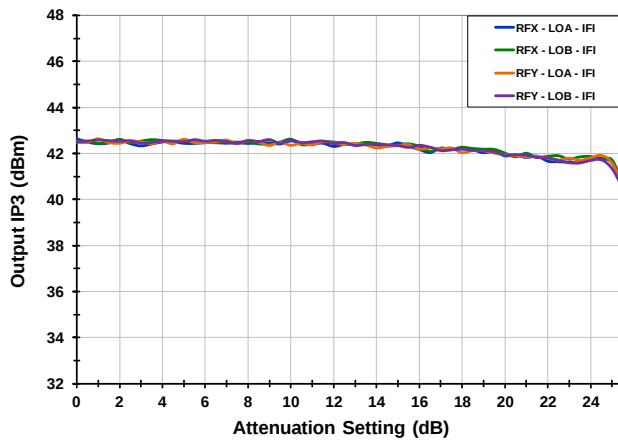
ATTN Accuracy [0.8 GHz RF, *HiSide* Inj.]



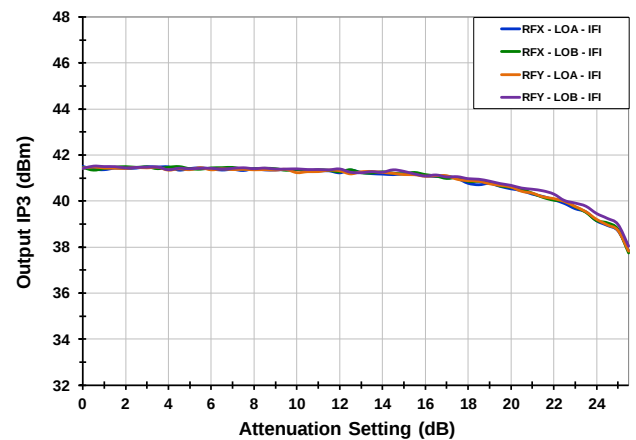
ATTN Accuracy [1.0 GHz RF, *HiSide* Inj.]



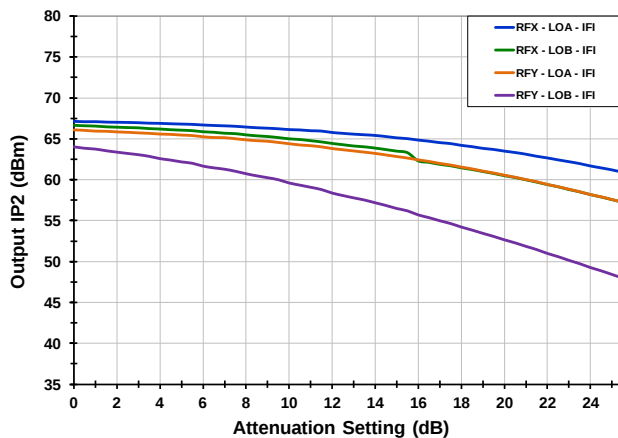
IP3₀ [0.8 GHz RF, *HiSide* Inj.]



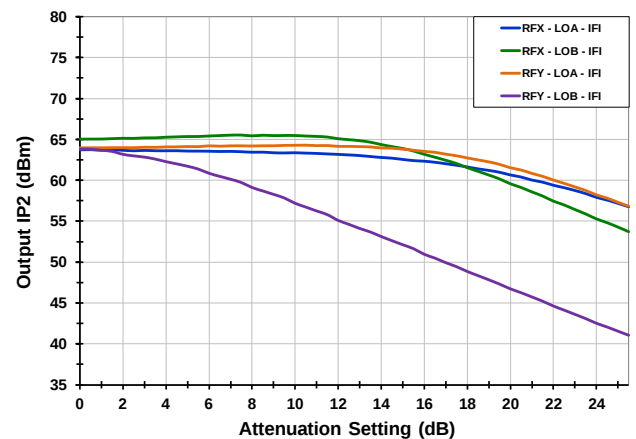
IP3₀ [1.0 GHz RF, *HiSide* Inj.]



IP2₀ [0.8 GHz RF, *HiSide* Inj.]

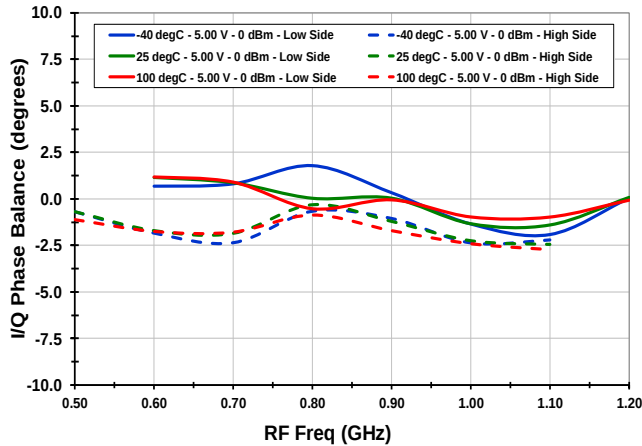


IP2₀ [1.0 GHz RF, *HiSide* Inj.]

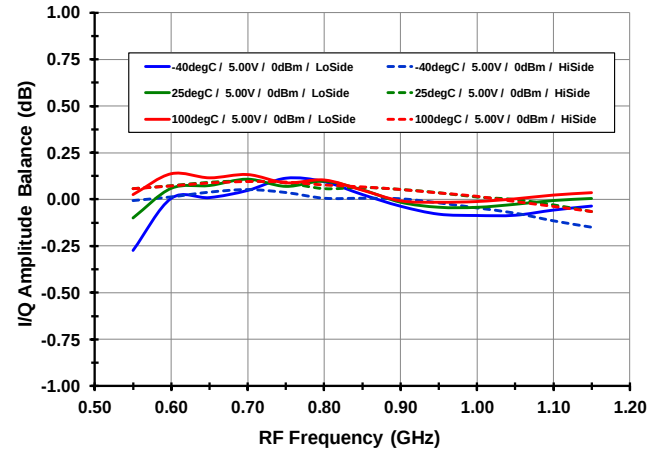


TOCs [Quadrature] (-10-)

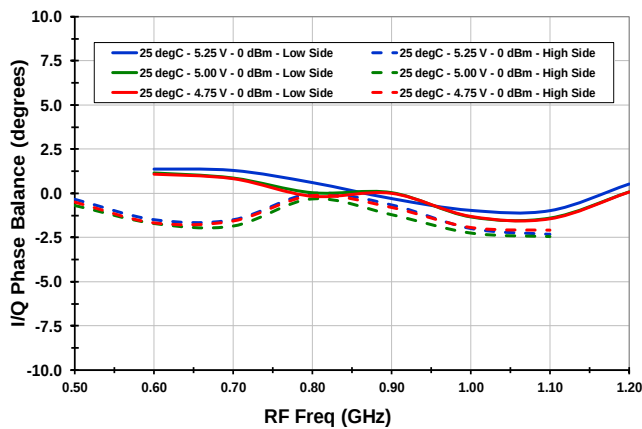
I/Q Phase Error vs. T_{CASE}



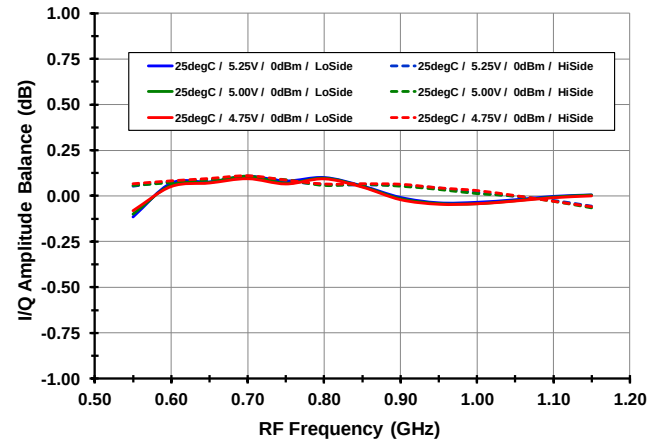
I/Q Amplitude Error vs. T_{CASE}



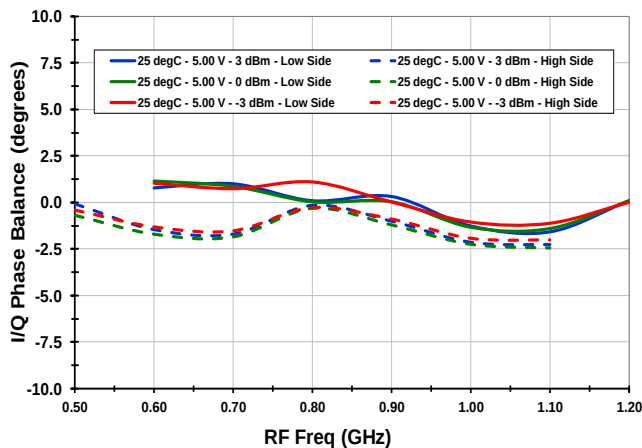
I/Q Phase Error vs. V_{CC}



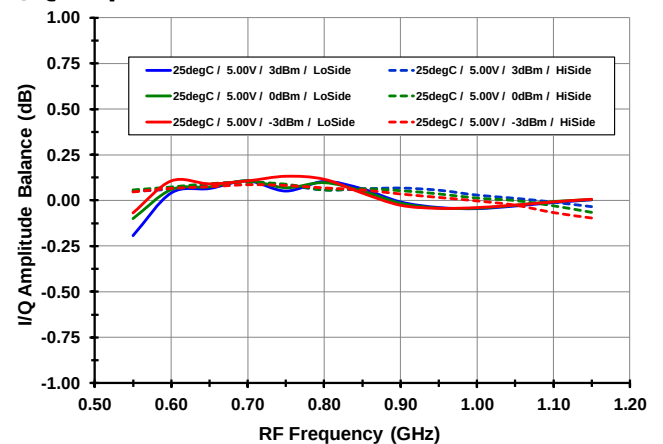
I/Q Amplitude Error vs. V_{CC}



I/Q Phase Error vs. LO level

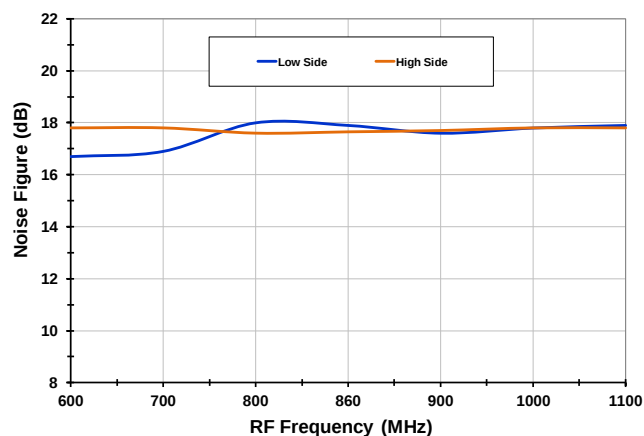


I/Q Amplitude Error vs. LO level

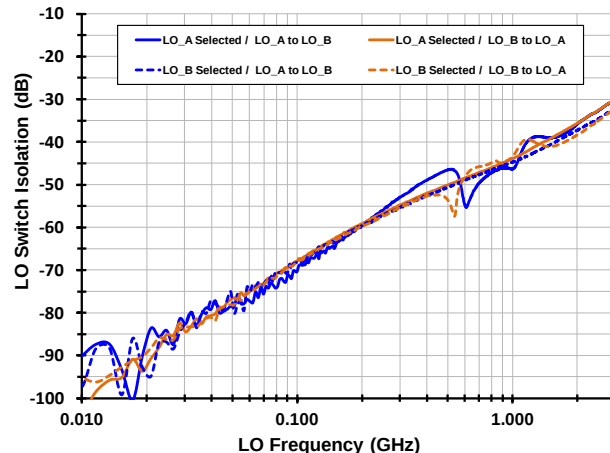


TOCs [NF, Switch Iso, Port Matches] (-11-)

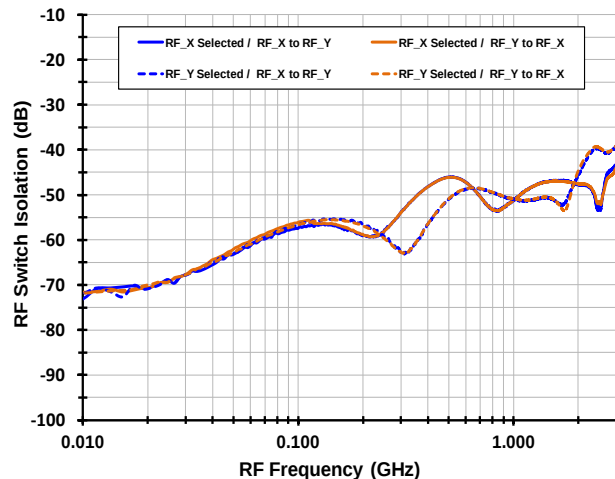
Noise Figure



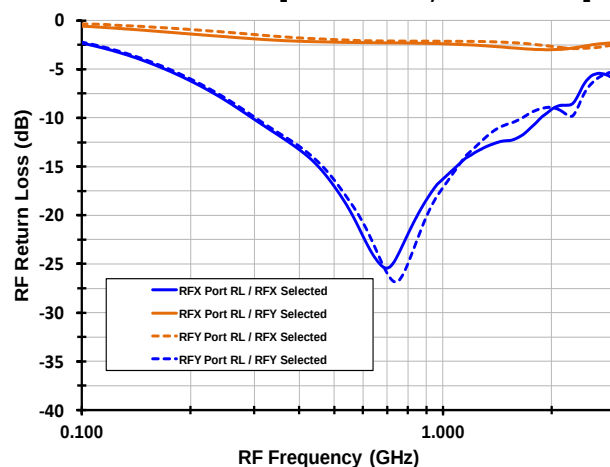
LO Switch Isolation



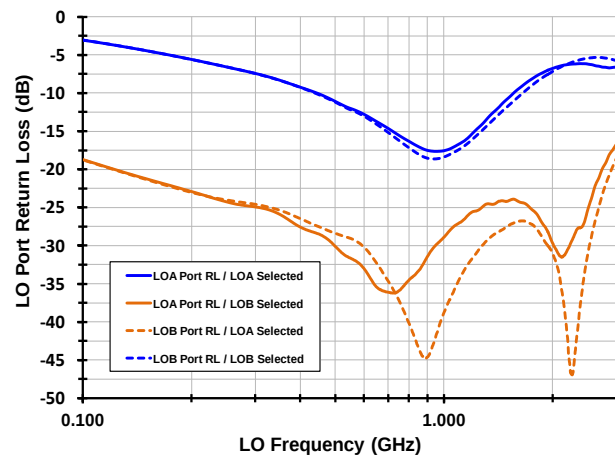
RF Switch Isolation



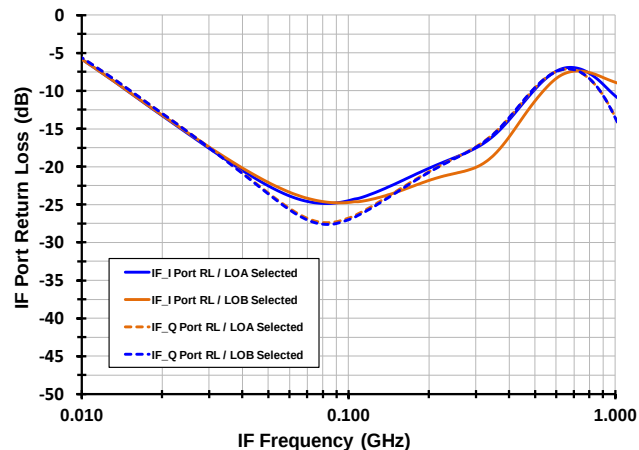
RF Port Return Loss [LO=1.06 GHz, LOA selected]



LO Port Return Loss



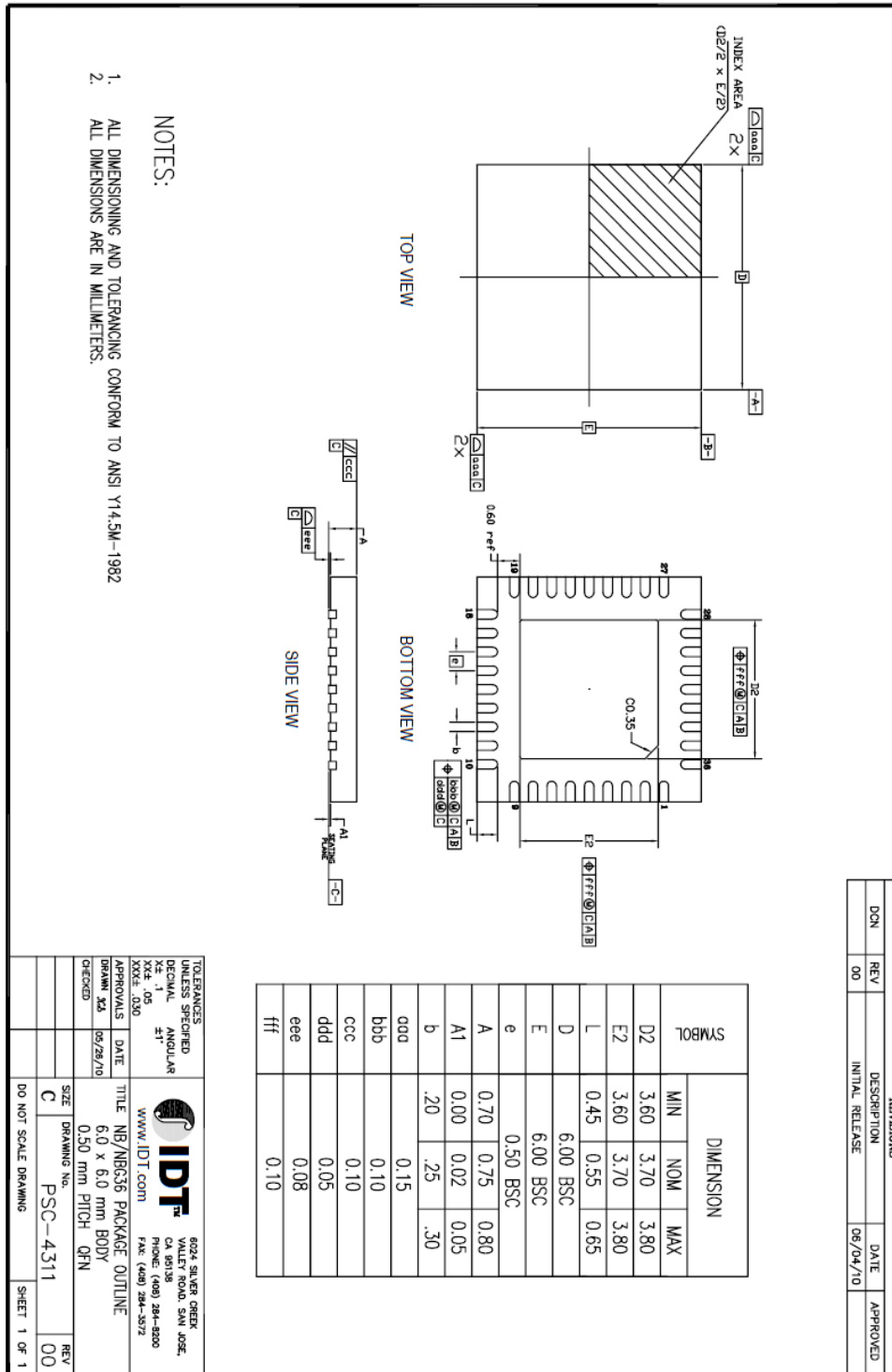
IF Port Return Loss



DPD Demodulator for PA Linearization

550MHz to 1150MHz

PACKAGE DRAWING (NBG36 6x6 QFN)

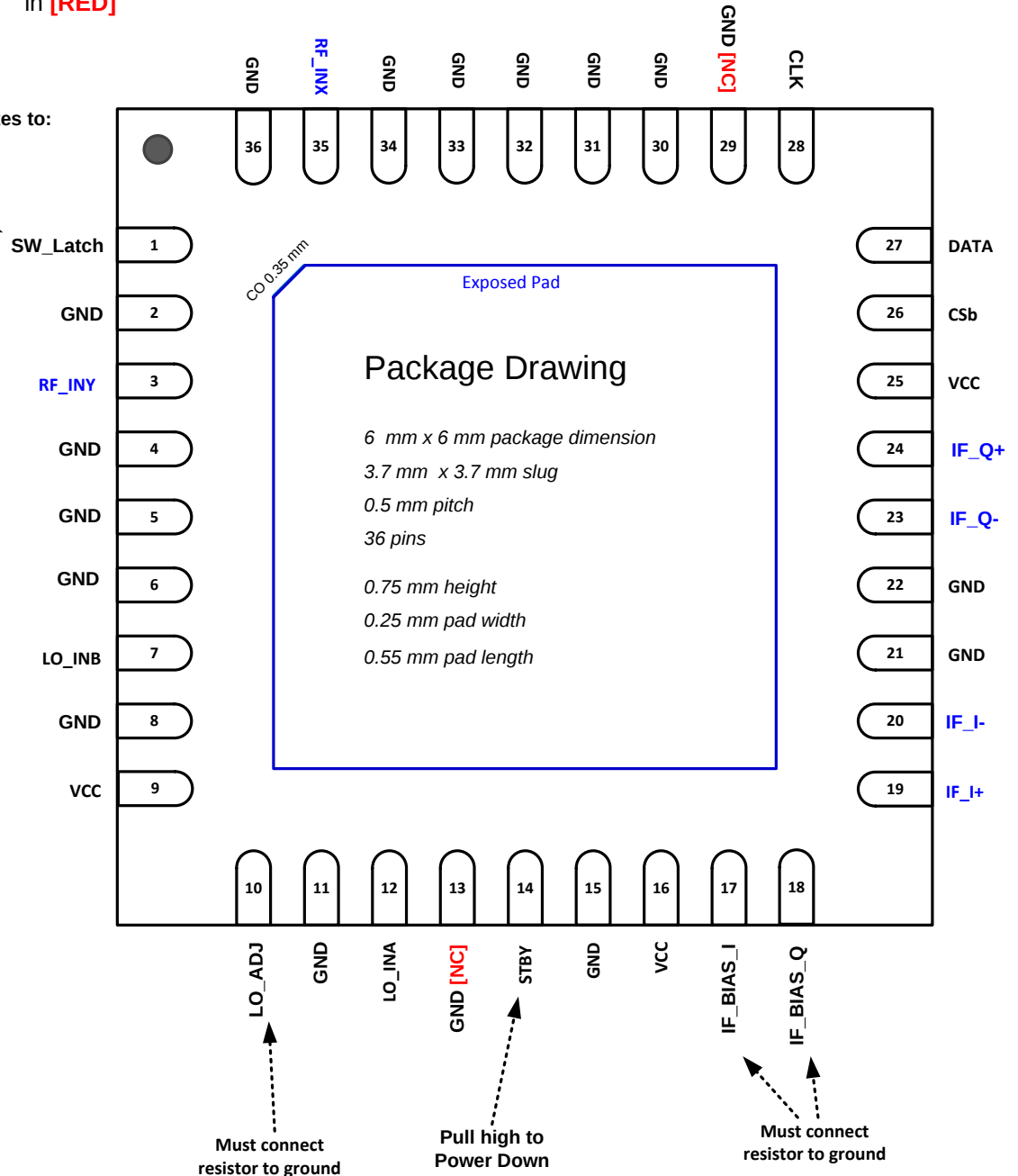


PIN DIAGRAM

Signal Path Inputs &
Outputs in **BLUE**

Internal Connections
in **[RED]**

Switch Latch
Pull High to Disable writes to:
A2:A0 in SPI = EN



PIN DESCRIPTIONS

Pins	Name	Function
1	SW_LATCH	Stand-by latch. Pull Low or Ground for Normal Operation. If left floating, this input will be internally pulled high, disabling SPI writes to ENb (Standby) and RF SW bits (A0, A2).
2, 4, 5, 6, 8, 11, 15, 21, 22, 30, 31, 32, 33, 34, 36	GND	Ground these Pins.
3	RF_INY	Alternate RF Input. Separated from RF_INX by internal SP2T. AC couple to this pin. Internally matched to 50 ohms
7	LO_INB	LO Input B. AC couple to this pin. Internally matched to 50 ohms. Selected via SPI port.
9, 16, 25	VCC	Power Supply. Bypass to GND with capacitors shown in the Typical Application Circuit as close as possible to pin.
10	LO_ADJ	Connect the specified resistor from this pin to ground to set the LO path I_{CC} . This IS a current setting resistor
12	LO_INA	LO Input A. AC couple to this pin. Internally matched to 50 ohms. Selected via SPI port.
13, 29	N.C.	No Connection. Not internally connected. OK to connect to Vcc. Recommended Connection is Ground
14	STBY	STBY Mode. Pull this pin high for Standby mode (30mA). Pull low or Ground for normal Operation
17, 18	IF_BIAS_I IF_BIAS_Q	Connect the specified resistor from this pin to ground to set the IF amplifier bias reference. This is NOT a current setting resistor
19, 20	IF_I+, IF_I-	<i>In-Phase</i> Mixer Differential IF Output. Connect pullup inductors from each of these pins to V _{CC} (see the Typical Application Circuit).
23, 24	IF_Q-, IF_Q+	<i>Quadrature</i> Mixer Differential IF Output. Connect pullup inductors from each of these pins to V _{CC} (see the Typical Application Circuit).
26	CSb	Chip Select Bar. The falling edge initiates a programming cycle and the rising edge latches the programmed shift register data into the active register.
27	DATA	Serial Data Input
28	CLK	Serial Clock Input
35	RF_INX	Main RF Input. Separated from RF_INY by internal SP2T. AC couple to this pin. Internally matched to 50 ohms
	— EP	Exposed Pad. Internally connected to GND. Solder this exposed pad to a PCB pad that uses multiple ground vias to provide heat transfer out of the device into the PCB ground planes. These multiple via grounds are also required to achieve the noted RF performance.

**CONTROL PIN VOLTAGE & RESISTANCE VALUES**

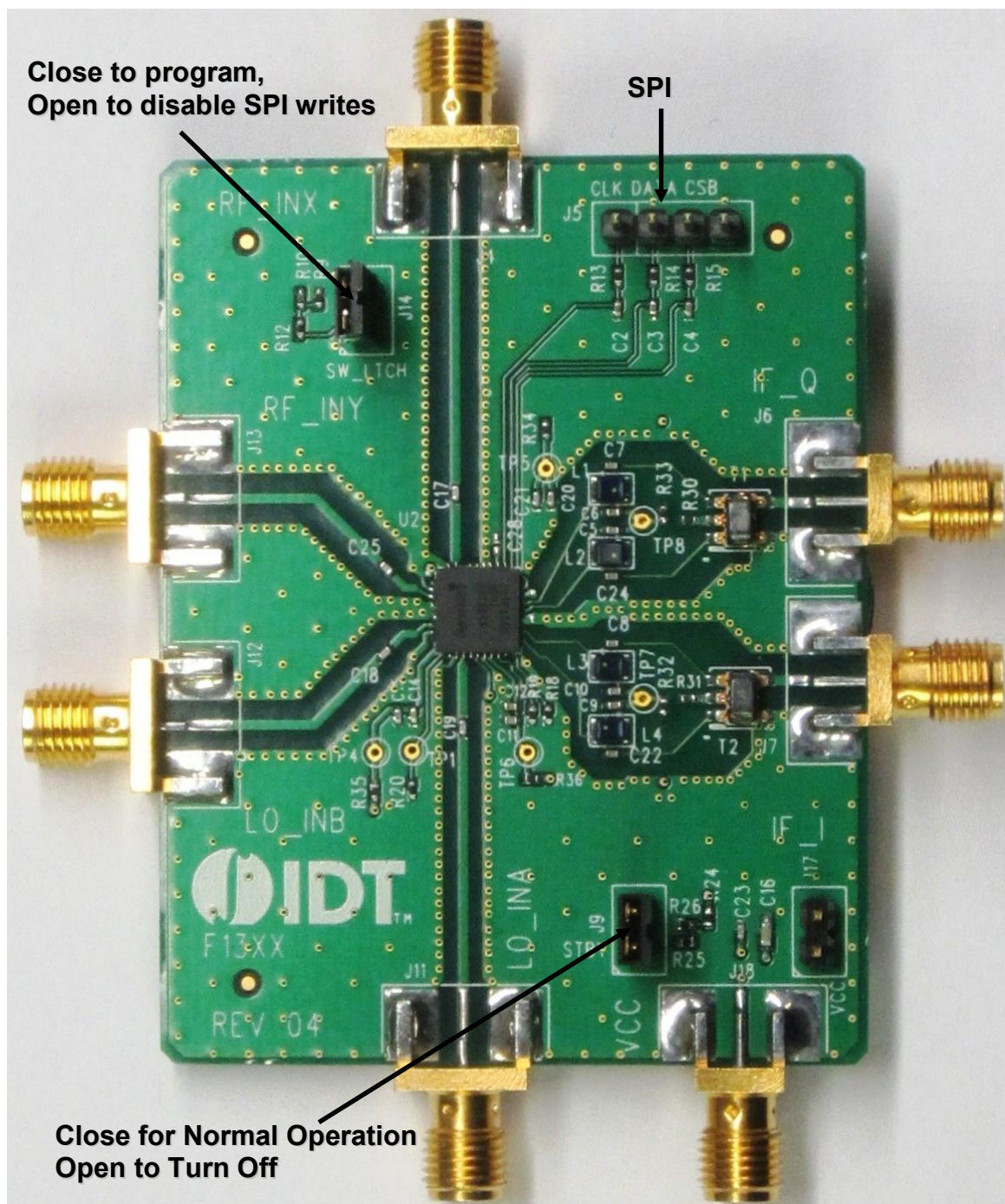
The following table provides open-circuit DC voltage and resistance values referenced to ground for each of the control pins listed.

Pin	Name	DC voltage (volts)	Resistance (ohms)
1	SW_LATCH	1.75	1.6M
14	STBY	5	50k
26	CSb	1.75	1.6M
27	DATA	1.75	1.6M
28	CLK	1.75	1.6M

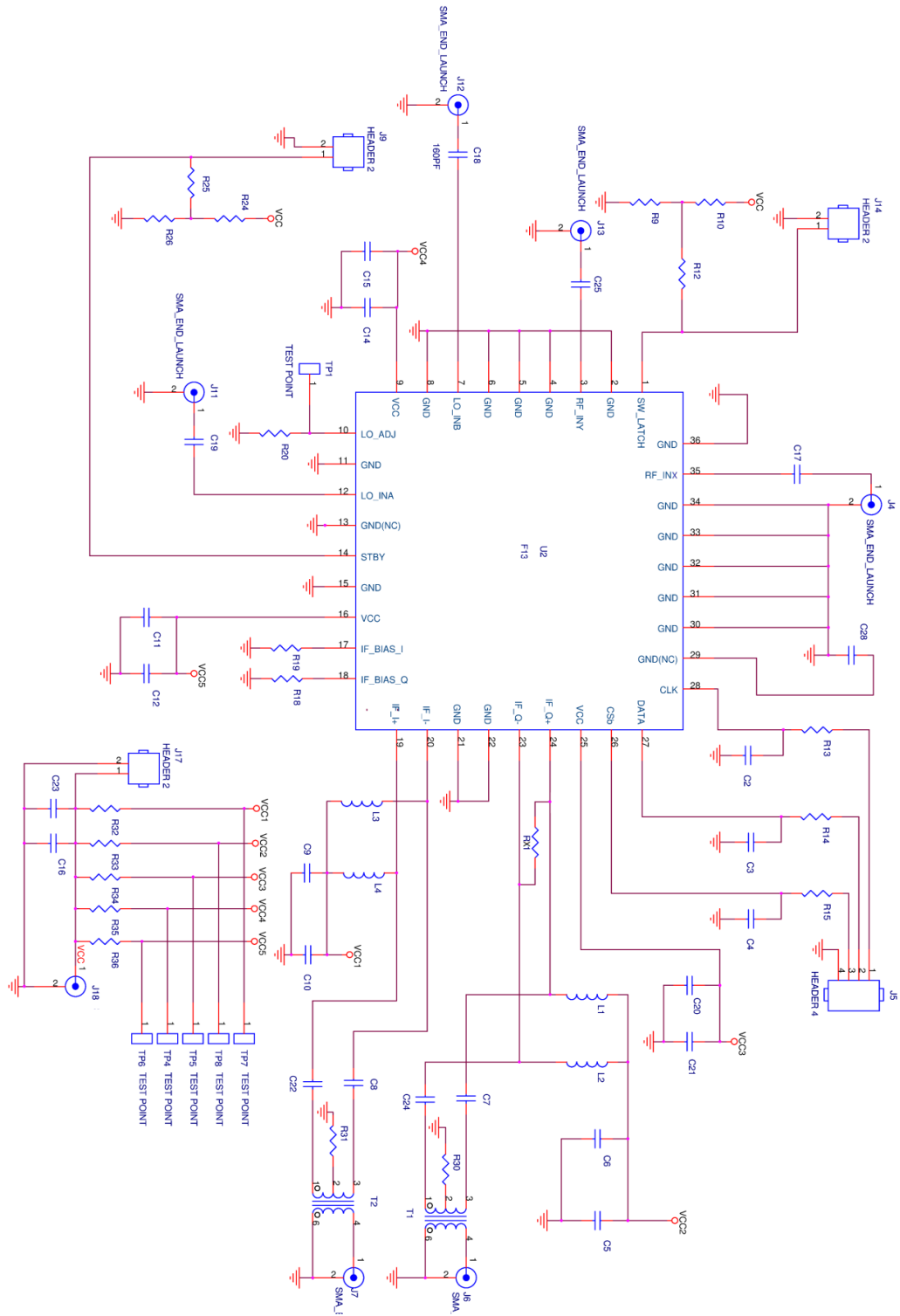
POWER SUPPLIES

All supply pins should be bypassed with external capacitors to minimize noise and fast transients. Supply noise can degrade noise figure and fast transients can trigger ESD clamps and cause them to fail. Supply voltage change or transients should have a slew rate smaller than 1V/20uS. In addition, all control pins should remain at 0V (+/-0.3V) while the supply voltage ramps or while it returns to zero.

EVKIT PICTURE / LAYOUT / OPERATION



EVKIT / APPLICATIONS CIRCUIT





IDTF1320NBGI Datasheet

DPD Demodulator for PA Linearization

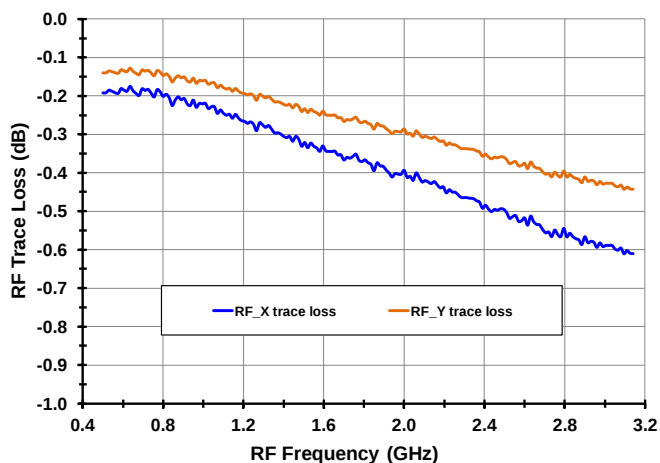
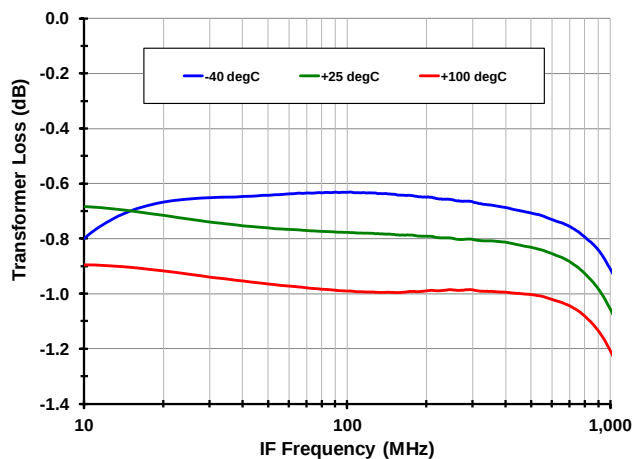
550MHz to 1150MHz

EVKIT BOM

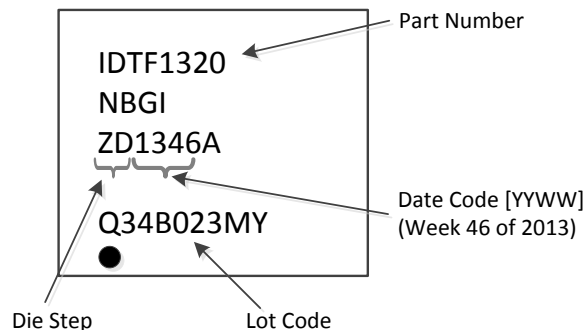
F1320

PCB Rev4 BOM							
Item #	Value	Size	Desc	Mfr. Part #	Mfr.	Part Reference	Qty
1	10nF	0402	CAP CER 10000PF 16V 10% X7R 0402	GRM155R71C103KA01D	MURATA	C6,7,8,9,12,14,21,22,24	9
2	1000pF	0402	CAP CER 1000PF 50V C0G 0402	GRM1555C1H102JA01D	MURATA	C5,10,11,15,20,23	6
3	100pF	0402	CAP CER 100PF 50V C0G 0402	0402CS-1N2XJLU	COILCRAFT	C2,3,4	3
4	160pF	0402	CAP CER 160PF 50V 5% NP0 0402	GRM1555C1H161JA01D	MURATA	C17,18,19,25	4
5	10uF	0603	CAP CER 10UF 6.3V X5R 0603	GRM188R60J106ME47D	MURATA	C16	1
6	Header 2 Pin	TH 2	CONN HEADER VERT SGL 2POS GOLD	961102-6404-AR	3M	J9,14,17	3
7	Header 4 Pin	TH 4	CONN HEADER VERT SGL 4POS GOLD	961104-6404-AR	3M	J5	1
8	SMA_END_LAUNCH	.062	SMA_END_LAUNCH (Small)	142-0711-821	Emerson Johnson	J6,7,18	3
9	SMA_END_LAUNCH	.062	SMA_END_LAUNCH (Big)	142-0701-851	Emerson Johnson	J4,11,12,13	4
10	1uH	0805	0805LS (2012) Ceramic Chip Inductor	0805LS-102XJLB	COILCRAFT	L1,2,3,4	4
11	43K	0402	RES 43K OHM 1/10W 1% 0402 SMD	ERJ-2RKF4302X	Panasonic	R10,24	2
12	75K	0402	RES 75K OHM 1/10W 1% 0402 SMD	ERJ-2RKF7502X	Panasonic	R9,26	2
13	2.80K	0402	RES 2.80K OHM 1/10W 1% 0402 SMD	ERJ-2RKF2801X	Panasonic	R20	1
14	121	0402	RES 121 OHM 1/10W 1% 0402 SMD	ERJ-2RKF1210X	Panasonic	R18,19	2
15	47K	0402	RES 47.0K OHM 1/16W 1% 0402 SMD	RC0402FR-0747KL	Yageo	R12,25	2
16	0	0402	RES 0.0 OHM 1/10W 0402 SMD	ERJ-2GE0R00X	Panasonic	R13,14,15,30,31,32,33,34,35,36	10
17	1:4 Balun	SM-22	SMT TRANSFORMER 10MHZ-1.9GHZ	RFXF6553-TR13	RFMD	T1,2	2
18	F13XX	QFN-36	DPD Demodulator	F13XX EV Kit Rev 04	IDT	U1	1
19	PCB		PCB Rev 04	F13XX EV Kit Rev 04			1
						Total	61

EVKIT LOSSES



TOP MARKINGS



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[IDT \(Integrated Device Technology\):](#)

[F1320NBGI8](#) [F1320NBGI](#)